

TL08xx FET 输入运算放大器

1 特性

- 高压摆率：20V/μs (TL08xH, 典型值)
- 低失调电压：1mV (TL08xH, 典型值)
- 低失调电压漂移：2 μV/°C
- 低功耗：940 μA/通道 (TL08xH, 典型值)
- 宽共模和差分电压范围
 - 共模输入电压范围包括 V_{CC+}
- 低输入偏置和失调电流
- 低噪声：
 - $f = 1\text{kHz}$ 时, $V_n = 18\text{nV}/\sqrt{\text{Hz}}$ (典型值)
- 输出短路保护
- 低总计谐波失真：0.003% (典型值)
- 宽电源电压：
 - $\pm 2.25\text{V}$ 至 $\pm 20\text{V}$, 4.5V 至 40V

2 应用

- 太阳能：串式和中央逆变器
- 电机驱动器：交流和伺服驱动控制及功率级模块
- 单相在线式 UPS
- 三相 UPS
- 专业音频混合器
- 电池测试设备

3 说明

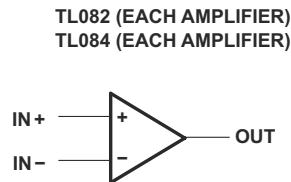
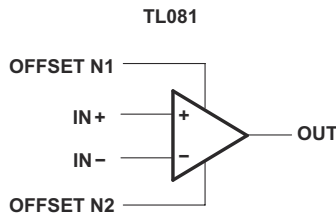
TL08xH (TL081H、TL082H 和 TL084H) 系列器件是业界通用的 TL08x (TL081、TL082 和 TL084) 器件的下一代版本。这些器件为成本敏感型应用提供了卓越的价值，其特性包括低失调电压 (1mV, 典型值)、高压摆率 (20V/μs) 和正电源的共模输入。得益于高 ESD (1.5kV, HBM)、集成 EMI 和射频滤波器以及 -40°C 至 125°C 的完整运行温度范围，TL08xH 器件可用于要求严苛的应用。

器件信息

器件型号	封装 ⁽¹⁾	本体尺寸 (标称值) ⁽²⁾
TL081x	P (PDIP, 8)	9.59mm × 6.35mm
	DCK (SC70, 5)	2mm × 1.25mm
	PS (SO, 8)	6.2mm × 5.3mm
	D (SOIC, 8)	4.9mm × 3.9mm
	DBV (SOT-23, 5)	2.9mm × 1.6mm
TL082x	P (PDIP, 8)	9.59mm × 6.35mm
	PS (SO, 8)	6.2mm × 5.3mm
	D (SOIC, 8)	4.9mm × 3.9mm
	DDF (SOT-23, 8)	2.9mm × 1.6mm
	PW (TSSOP, 8)	4.4mm × 3mm
TL082M	JG (CDIP, 8)	9.6mm × 6.67mm
	FK (LCCC, 20)	8.89mm × 8.89mm
TL084x	N (PDIP, 14)	19.3mm × 6.35mm
	NS (SO, 14)	10.3mm × 5.3mm
	D (SOIC, 14)	8.65mm × 3.91mm
	DYY (SOT-23, 14)	4.2mm × 2mm
	PW (TSSOP, 14)	5mm × 4.4mm
TL084M	J (CDIP, 14)	19.56mm × 6.67mm
	FK (LCCC, 20)	8.89mm × 8.89mm

(1) 有关更多信息，请参阅节 11。

(2) 本体尺寸 (长 × 宽) 为标称值，不包括引脚。



逻辑符号



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4 Pin Configuration and Functions

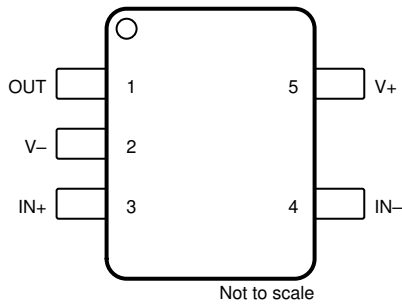


图 4-1. TL081H DBV Package,
5-Pin SOT-23
(Top View)

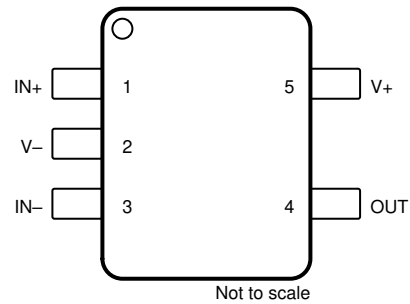
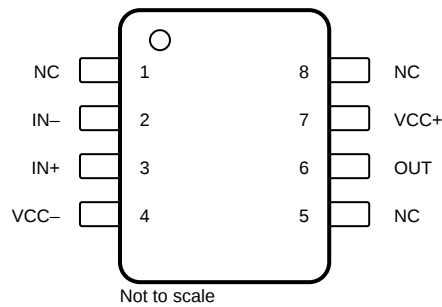


图 4-2. TL081H DCK Package,
5-Pin SC70
(Top View)



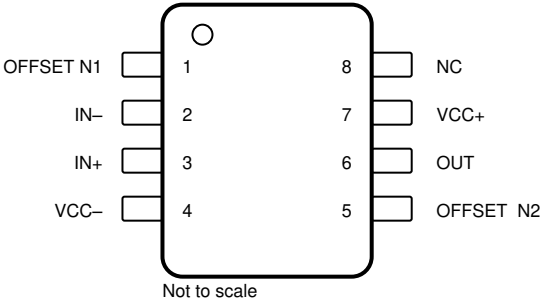
NC- no internal connection

图 4-3. TL081H D Package,
8-Pin SOIC
(Top View)

表 4-1. Pin Functions: TL081H

NAME	PIN			TYPE ⁽¹⁾	DESCRIPTION
	DBV	DCK	D		
IN -	4	3	2	I	Inverting input
IN+	3	1	3	I	Noninverting input
NC	—	—	8	—	Do not connect
NC	—	—	1	—	Do not connect
NC	—	—	5	—	Do not connect
OUT	1	4	6	O	Output
VCC -	2	2	4	—	Power supply
VCC+	5	5	7	—	Power supply

(1) I = input, O = output



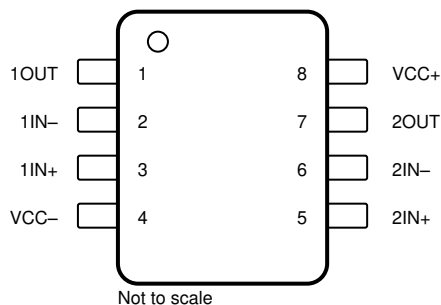
NC- no internal connection

图 4-4. TL081x D, P, and PS Package,
8-Pin SOIC, PDIP, and SO
(Top View)

表 4-2. Pin Functions: TL081x

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
IN -	2	I	Inverting input
IN+	3	I	Noninverting input
NC	8	—	Do not connect
OFFSET N1	1	—	Input offset adjustment
OFFSET N2	5	—	Input offset adjustment
OUT	6	O	Output
VCC -	4	—	Power supply
VCC+	7	—	Power supply

(1) I = input, O = output

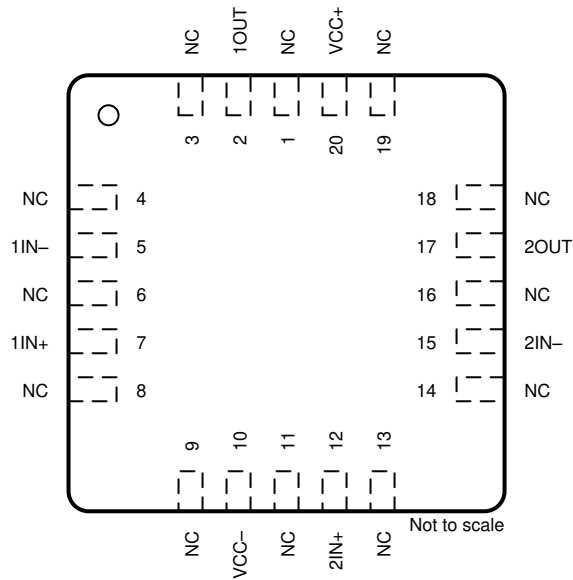


**图 4-5. TL082x D, DDF, DGK, JG, P, PS, and PW Package,
 8-Pin SOIC, SOT-23 (8), VSSOP, CDIP, PDIP, SO, and TSSOP
 (Top View)**

表 4-3. Pin Functions: TL082x

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
1IN –	2	I	Inverting input
1IN+	3	I	Noninverting input
1OUT	1	O	Output
2IN –	6	I	Inverting input
2IN+	5	I	Noninverting input
2OUT	7	O	Output
VCC –	4	—	Power supply
VCC+	8	—	Power supply

(1) I = input, O = output



NC- no internal connection

图 4-6. TL082 FK Package,
20-Pin LCCC
(Top View)

表 4-4. Pin Functions: TL082x

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
1IN -	5	I	Inverting input
1IN+	7	I	Noninverting input
1OUT	2	O	Output
2IN -	15	I	Inverting input
2IN+	12	I	Noninverting input
2OUT	17	O	Output
NC	1, 3, 4, 6, 8, 9, 11, 13, 14, 16, 18, 19	—	Do not connect
VCC -	10	—	Power supply
VCC+	20	—	Power supply

(1) I = input, O = output

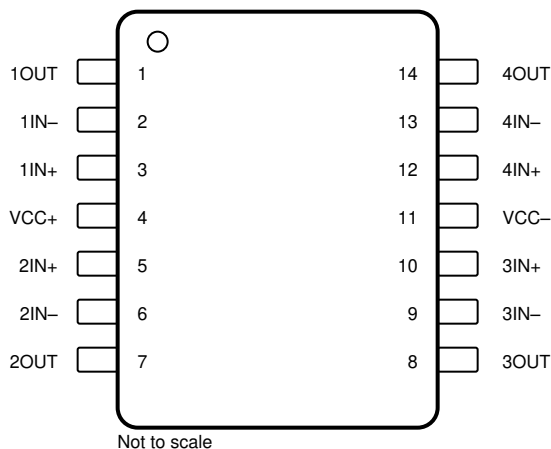
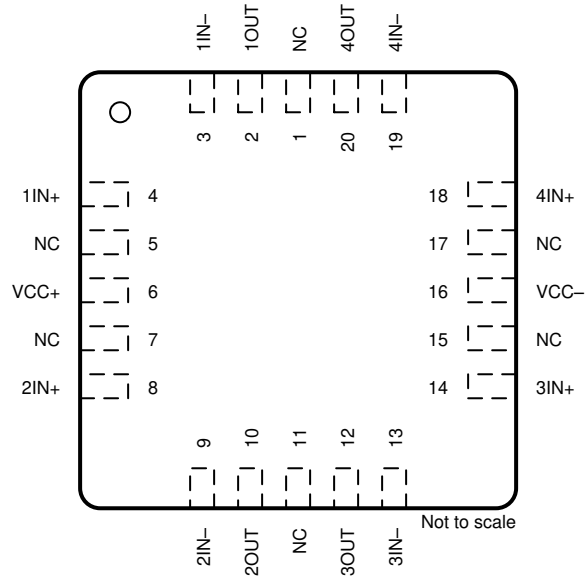


图 4-7. TL084x D, N, NS, PW, J, and DYY Package,
14-Pin SOIC, PDIP, SO, TSSOP, CDIP, and SOT-23 (14)
(Top View)

表 4-5. Pin Functions: TL084x

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
1IN -	2	I	Inverting input
1IN+	3	I	Noninverting input
1OUT	1	O	Output
2IN -	6	I	Inverting input
2IN+	5	I	Noninverting input
2OUT	7	O	Output
3IN -	9	I	Inverting input
3IN+	10	I	Noninverting input
3OUT	8	O	Output
4IN -	13	I	Inverting input
4IN+	12	I	Noninverting input
4OUT	14	O	Output
V _{CC} -	11	—	Power supply
V _{CC} +	4	—	Power supply

(1) I = input, O = output



NC- no internal connection

图 4-8. TL084 FK Package,
20-Pin LCCC
(Top View)

表 4-6. Pin Functions: TL084x

PIN		TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.		
1IN -	3	I	Inverting input
1IN+	4	I	Noninverting input
1OUT	2	O	Output
2IN -	9	I	Inverting input
2IN+	8	I	Noninverting input
2OUT	10	O	Output
3IN -	13	I	Inverting input
3IN+	14	I	Noninverting input
3OUT	12	O	Output
4IN -	19	I	Inverting input
4IN+	18	I	Noninverting input
4OUT	20	O	Output
NC	1, 5, 7, 11, 15, 17	—	Do not connect
VCC -	16	—	Power supply
VCC+	6	—	Power supply

(1) I = input, O = output

5 Specifications

5.1 Absolute Maximum Ratings

over operating ambient temperature range (unless otherwise noted) ⁽¹⁾

			MIN	MAX	UNIT
Supply voltage, $V_S = (V+) - (V-)$		All NS and PS packages; All TL08xM devices	- 0.3	36	V
		All other devices	0	42	V
Signal input pins	Common-mode voltage ⁽³⁾	All NS and PS packages; All TL08xM devices	$(V-) - 0.3$	$(V-) + 36$	V
		All other devices	$(V-) - 0.5$	$(V+) + 0.5$	V
	Differential voltage ⁽³⁾	All NS and PS packages; All TL08xM devices ⁽⁴⁾	$(V-) - 0.3$	$(V-) + 36$	V
		All other devices		$V_S + 0.2$	V
	Current ⁽³⁾	All NS and PS packages; All TL07xM devices		50	mA
		All other devices	- 10	10	mA
Output short-circuit ⁽²⁾			Continuous		
Operating ambient temperature, T_A			- 55	150	°C
Junction temperature, T_J				150	°C
Case temperature for 60 seconds - FK package				260	°C
Lead temperature 1.8 mm (1/16 inch) from case for 10 seconds				300	°C
Storage temperature, T_{stg}			- 65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Short-circuit to ground, one amplifier per package.
- (3) Input pins are diode-clamped to the power-supply rails. Input signals that may swing more than 0.5V beyond the supply rails must be current limited to 10 mA or less.
- (4) Differential voltage only limited by input voltage.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	

- (1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating ambient temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_S	Supply voltage, $(V+) - (V-)$	All NS and PS packages; All TL08xM devices ⁽¹⁾	10	30	V
		All other devices	4.5	40	V
V_I	Input voltage range	All NS and PS packages; All TL08xM devices	$(V-) + 2$	$(V+) + 0.1$	V
		All other devices	$(V-) + 4$	$(V+) + 0.1$	V
T_A	Specified temperature	TL08xM	- 55	125	°C
		TL08xH	- 40	125	°C
		TL08xI	- 40	85	°C
		TL08xC	0	70	°C

- (1) $V+$ and $V-$ are not required to be of equal magnitude, provided that the total V_S ($V+ - V-$) is between 10V and 30V.

5.4 Thermal Information for Single Channel

THERMAL METRIC ⁽¹⁾		TL081xx					UNIT
		D (SOIC)	DCK (SC70)	DBV (SOT-23)	P (PDIP)	PS (SO)	
		8 PINS	5 PINS	5 PINS	8 PINS	8 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	158.8	217.5	212.2	85	95	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	98.6	113.1	111.1	–	–	°C/W
R _{θJB}	Junction-to-board thermal resistance	102.3	63.8	79.4	–	–	°C/W
ψ _{JT}	Junction-to-top characterization parameter	45.8	34.8	51.8	–	–	°C/W
ψ _{JB}	Junction-to-board characterization parameter	101.5	63.5	79.0	–	–	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

5.5 Thermal Information for Dual Channel

THERMAL METRIC ⁽¹⁾		TL082xx								UNIT
		D (SOIC)	DDF (SOT-23)	FK (LCCC)	JG (CDIP)	P (PDIP)	PS (SO)	PW (TSSOP)	U (CFP)	
		8 PINS	8 PINS	20 PINS	8 PINS	8 PINS	8 PINS	8 PINS	10 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	147.8	181.5	–	–	85	95	200.3	169.8	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	88.2	112.5	5.61	15.05	–	–	89.4	62.1	°C/W
R _{θJB}	Junction-to-board thermal resistance	91.4	98.2	–	–	–	–	131.0	176.2	°C/W
ψ _{JT}	Junction-to-top characterization parameter	36.8	17.2	–	–	–	–	22.2	48.4	°C/W
ψ _{JB}	Junction-to-board characterization parameter	90.6	97.6	–	–	–	–	129.3	144.1	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	–	–	–	–	N/A	5.4	°C/W

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

5.6 Thermal Information for Quad Channel

THERMAL METRIC ⁽¹⁾		TL084xx								UNIT
		D (SOIC)	DYY (SOT-23)	FK (TSSOP)	J (TSSOP)	N (TSSOP)	NS (TSSOP)	PW (TSSOP)	W (TSSOP)	
		14 PINS	14 PINS	20 PINS	14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	114.2	153.2	–	–	80	76	–	128.8	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	70.3	88.7	5.61	14.5	–	–	14.5	56.1	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	70.2	65.4	–	–	–	–	–	127.6	°C/W
ψ_{JT}	Junction-to-top characterization parameter	28.8	9.5	–	–	–	–	–	29	°C/W
ψ_{JB}	Junction-to-board characterization parameter	69.8	65.0	–	–	–	–	–	106.1	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	N/A	N/A	–	–	–	–	–	0.5	°C/W

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

5.7 Electrical Characteristics: TL08xH

For $V_S = (V_{CC+}) - (V_{CC-}) = 4.5V$ to $40V$ ($\pm 2.25V$ to $\pm 20V$) at $T_A = 25^\circ C$, $R_L = 10k\Omega$ connected to $V_S / 2$, $V_{CM} = V_S / 2$, and $V_{OUT} = V_S / 2$, unless otherwise noted.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
OFFSET VOLTAGE							
V _{OS}	Input offset voltage			±1	±4	mV	
			T _A = - 40°C to 125°C		±5		
dV _{OS} /dT	Input offset voltage drift		T _A = - 40°C to 125°C	±2		μV/°C	
PSRR	Input offset voltage versus power supply	V _S = 5V to 40V, V _{CM} = V _S / 2	T _A = - 40°C to 125°C	±1	±10	μ V/V	
	Channel separation	f = 0Hz		10		μV/V	
INPUT BIAS CURRENT							
I _B	Input bias current			±1	±120	pA	
			DCK and DBV packages	±1	±300	pA	
			T _A = - 40°C to 125°C ⁽¹⁾		±5	nA	
I _{OS}	Input offset current			±0.5	±120	pA	
			DCK and DBV packages	±0.5	±250	pA	
			T _A = - 40°C to 125°C ⁽¹⁾		±5	nA	
NOISE							
E _N	Input voltage noise	f = 0.1Hz to 10Hz		9.2		μ V _{PP}	
				1.4		μV _{RMS}	
e _N	Input voltage noise density	f = 1kHz		37		nV/ √ Hz	
		f = 10kHz		21			
i _N	Input current noise	f = 1kHz		80		fA/ √ Hz	
INPUT VOLTAGE RANGE							
V _{CM}	Common-mode voltage range			(V _{CC-}) + 1.5	(V _{CC+})	V	
CMRR	Common-mode rejection ratio	V _S = 40V, (V _{CC-}) + 2.5V < V _{CM} < (V _{CC+}) - 1.5V		100	105	dB	
			T _A = - 40°C to 125°C	95		dB	
		V _S = 40V, (V _{CC-}) + 2.5V < V _{CM} < (V _{CC+})		90	105	dB	
			T _A = - 40°C to 125°C	80		dB	
INPUT CAPACITANCE							
Z _{ID}	Differential			100 2		M Ω pF	
Z _{ICM}	Common-mode			6 1		T Ω pF	
OPEN-LOOP GAIN							
A _{OL}	Open-loop voltage gain	V _S = 40V, V _{CM} = V _S / 2, (V _{CC-}) + 0.3V < V _O < (V _{CC+}) - 0.3V	T _A = - 40°C to 125°C	118	125	dB	
A _{OL}	Open-loop voltage gain	V _S = 40V, V _{CM} = V _S / 2, R _L = 2k Ω, (V _{CC-}) + 1.2V < V _O < (V _{CC+}) - 1.2V	T _A = - 40°C to 125°C	115	120	dB	
FREQUENCY RESPONSE							
GBW	Gain-bandwidth product			5.25		MHz	
SR	Slew rate	V _S = 40V, G = +1, C _L = 20pF		20		V/ μ s	
t _S	Settling time	To 0.1%, V _S = 40V, V _{STEP} = 10V , G = +1, CL = 20pF		0.63		μ s	
		To 0.1%, V _S = 40V, V _{STEP} = 2V , G = +1, CL = 20pF		0.56			
		To 0.01%, V _S = 40V, V _{STEP} = 10V , G = +1, CL = 20pF		0.91			
		To 0.01%, V _S = 40V, V _{STEP} = 2V , G = +1, CL = 20pF		0.48			
	Phase margin	G = +1, R _L = 10kΩ, C _L = 20pF		56		°	
	Overload recovery time	V _{IN} × gain > V _S		300		ns	
THD+N	Total harmonic distortion + noise	V _S = 40V, V _O = 6V _{RMS} , G = +1, f = 1kHz		0.00012		%	

5.7 Electrical Characteristics: TL08xH (续)

For $V_S = (V_{CC+}) - (V_{CC-}) = 4.5V$ to $40V$ ($\pm 2.25V$ to $\pm 20V$) at $T_A = 25^\circ C$, $R_L = 10k\Omega$ connected to $V_S / 2$, $V_{CM} = V_S / 2$, and $V_{O UT} = V_S / 2$, unless otherwise noted.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
EMIRR	EMI rejection ratio	f = 1GHz		53			dB
OUTPUT							
	Voltage output swing from rail	Positive rail headroom	V _S = 40V, R _L = 10kΩ	115	210	mV	
			V _S = 40V, R _L = 2kΩ	520	965		
		Negative rail headroom	V _S = 40V, R _L = 10kΩ	105	215		
			V _S = 40V, R _L = 2kΩ	500	1030		
I _{SC}	Short-circuit current			±26			mA
C _{LOAD}	Capacitive load drive			300			pF
Z _O	Open-loop output impedance	f = 1MHz, I _O = 0 A		125			Ω
POWER SUPPLY							
I _Q	Quiescent current per amplifier	I _O = 0 A	T _A = - 40°C to 125°C	937.5	1125	μA	
		I _O = 0 A, (TL081H)		960	1156		
		I _O = 0 A			1130		
		I _O = 0 A, (TL082H)			1143		
		I _O = 0 A, (TL071H)			1160		
	Turn-On Time	At T _A = 25°C, V _S = 40V, V _S ramp rate > 0.3V/μs		60			μ s

(1) Max I_B and I_{OS} data is specified based on characterization results.

5.8 Electrical Characteristics (DC): TL08xC, TL08xAC, TL08xBC, TL08xI, TL08xM

For $V_S = (V_{CC+}) - (V_{CC-}) = \pm 15V$ at $T_A = 25^\circ C$, unless otherwise noted

PARAMETER		TEST CONDITIONS ^{(1) (2)}			MIN	TYP	MAX	UNIT
V _{OS}	Input offset voltage	V _O = 0V R _S = 50 Ω	TL08xC		3	10	mV	
				T _A = Full range	13			
			TL08xAC		3	6		
				T _A = Full range	7.5			
			TL08xBC		2	3		
				T _A = Full range	5			
			TL08xI		3	6		
				T _A = Full range	8			
			TL081M, TL082M		3	6		
T _A = Full range	9							
TL084M		3	9					
	T _A = Full range	15						
dV _{OS} /dT	Input offset voltage drift	V _O = 0V, R _S = 50 Ω	T _A = Full range		±18			μV/°C
I _{OS}	Input offset current	V _O = 0V	TL08xC		5	100	pA	
				T _A = Full range	10	nA		
			TL08xAC, TL08xBC, TL08xI		5	100	pA	
				T _A = Full range	2	nA		
			TL08xM		5	100	pA	
T _A = Full range	20	nA						
I _B	Input bias current	V _O = 0V	TL08xC, TL08xAC, TL08xBC, TL08xI		65	200	pA	
				T _A = Full range	7	nA		
			TL081M, TL082M		65	200	pA	
				T _A = Full range	50	nA		
			TL084M		65	200	pA	
T _A = Full range	20	nA						
V _{CM}	Common-mode voltage range				±11 – 12 to 15			V
V _{OM}	Maximum peak output voltage swing	R _L = 10k Ω	T _A = Full range		±12	±13.5	V	
		R _L ≥ 10k Ω			±12			
		R _L ≥ 2k Ω			±10			
A _{OL}	Open-loop voltage gain	V _O = 0V	TL08xC		25	200	V/mV	
				T _A = Full range	15			
			TL08xAC, TL08xBC, TL08xI		50	200		
				T _A = Full range	25			
			TL08xM		35	200		
T _A = Full range	15							
GBW	Gain-bandwidth product	All NS and PS packages; All TL08xM devices			3		MHz	
		All other devices			5.25			
R _{ID}	Common-mode input resistance				1		T Ω	
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICR(min)} V _O = 0V R _S = 50 Ω	TL08xC	70		100	dB	
			TL08xAC, TL08xBC, TL08xI	75		100		
			TL08xM	80		86		
PSRR	Input offset voltage versus power supply	V _S = ±9V to ± 18V V _O = 0V R _S = 50 Ω	TL08xC	70		100	dB	
			TL08xAC, TL08xBC, TL08xI	80		100		
			TL08xM	80		86		

5.8 Electrical Characteristics (DC): TL08xC, TL08xAC, TL08xBC, TL08xI, TL08xM (续)

For $V_S = (V_{CC+}) - (V_{CC-}) = \pm 15V$ at $T_A = 25^\circ C$, unless otherwise noted

PARAMETER		TEST CONDITIONS ^{(1) (2)}	MIN	TYP	MAX	UNIT
I_Q	Quiescent current per amplifier	$V_O = 0V$; no load		1.4	2.5	mA
	Channel separation	$f = 0Hz$		1		$\mu V/V$

- (1) All characteristics are measured under open-loop conditions with zero common-mode voltage, unless otherwise specified.
- (2) Full range is $T_A = 0^\circ C$ to $70^\circ C$ for the TL07xC, TL07xAC, and TL07xBC; $T_A = -40^\circ C$ to $85^\circ C$ for the TL07xI; and $T_A = -55^\circ C$ to $125^\circ C$ for the TL07xM.

5.9 Electrical Characteristics (AC): TL08xC, TL08xAC, TL08xBC, TL08xI, TL08xM

For $V_S = (V_{CC+}) - (V_{CC-}) = \pm 15V$ at $T_A = 25^\circ C$, unless otherwise noted.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
SR	Slew rate	$V_I = 10V, C_L = 100pF, R_L = 2k\Omega$	TL08xM	5	20		V/ μs
			TL08xC, TL08xAC, TL08xBC, TL08xI	8	20		V/ μs
t_S	Settling time	$V_I = 20V, C_L = 100pF, R_L = 2k\Omega$			0.1		μs
					20%		
e_N	Input voltage noise density	All PS and NS packages; All TL08xM devices	$R_S = 20\Omega, f = 1kHz$		18		nV/ $\sqrt{Hz}$
		All other devices	$f = 1kHz$		37		nV/ $\sqrt{Hz}$
			$f = 10kHz$		21		
E_N	Input voltage noise	All PS and NS packages; All TL08xM devices	$R_S = 20\Omega, f = 10Hz$ to 10kHz		4		μV_{RMS}
		All other devices	$f = 0.1Hz$ to 10Hz		1.4		μV_{RMS}
i_N	Input current noise	$R_S = 20\Omega, f = 1kHz$			10		fA/ $\sqrt{Hz}$
	Phase margin	TL08xC, TL08xAC, TL08xBC, TL08xI	$G = +1, R_L = 10k\Omega, C_L = 20pF$		56		°
	Overload recovery time	$V_{IN} \times \text{gain} > V_S$			300		ns
THD+N	Total harmonic distortion + noise	All PS and NS packages; All TL08xM devices	$V_O = 6V_{RMS}, R_L \geq 2k\Omega, f = 1kHz, G = +1, R_S \leq 1k\Omega$		0.003		%
		All other devices	$V_S = 40V, V_O = 6V_{RMS}, G = +1, f = 1kHz$		0.00012		%
EMIRR	EMI rejection ratio	TL08xC, TL08xAC, TL08xBC, TL08xI	$f = 1GHz$		53		dB
Z_O	Open-loop output impedance	TL07xC, TL07xAC, TL07xBC, TL07xI	$f = 1MHz, I_O = 0A$		125		Ω

5.10 Typical Characteristics: TL08xH

at $T_A = 25^\circ\text{C}$, $V_S = 40\text{V}$ ($\pm 20\text{V}$), $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{k}\Omega$ connected to $V_S / 2$, and $C_L = 20\text{pF}$ (unless otherwise noted)

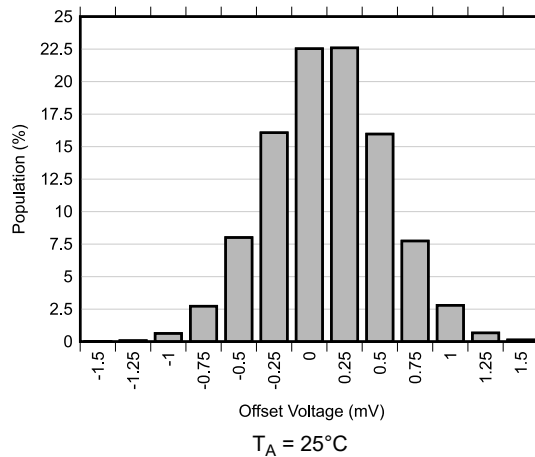


图 5-1. Offset Voltage Production Distribution

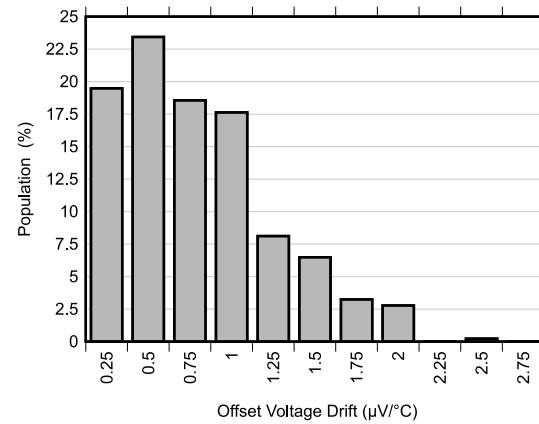


图 5-2. Offset Voltage Drift Distribution

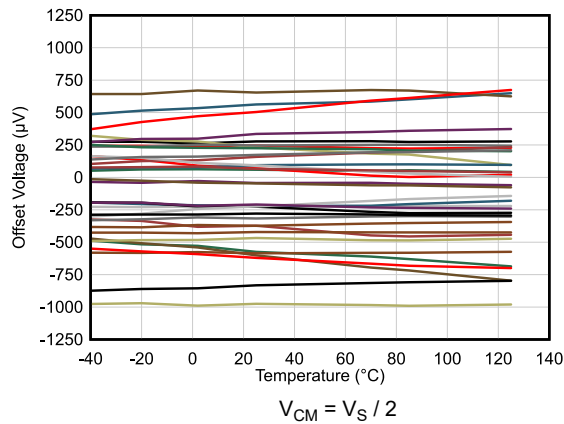


图 5-3. Offset Voltage vs Temperature

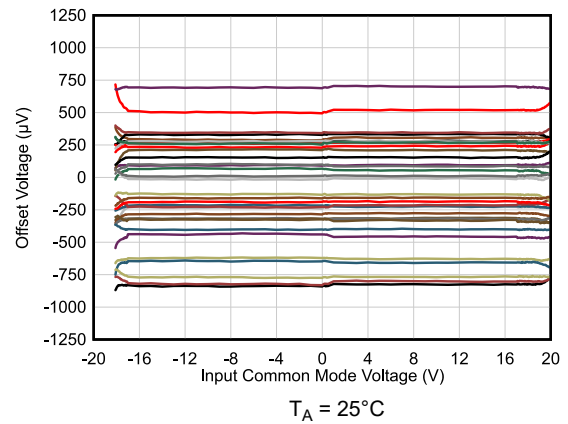


图 5-4. Offset Voltage vs Common-Mode Voltage

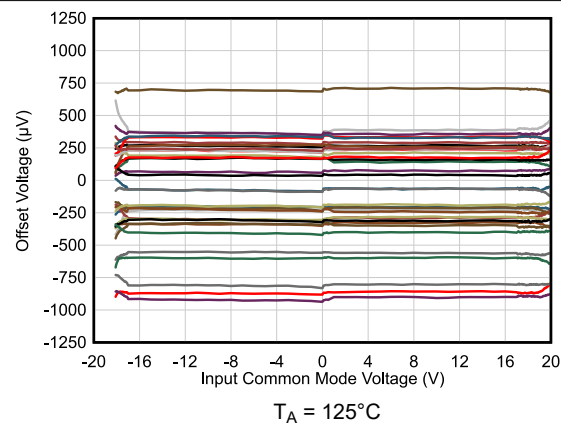


图 5-5. Offset Voltage vs Common-Mode Voltage

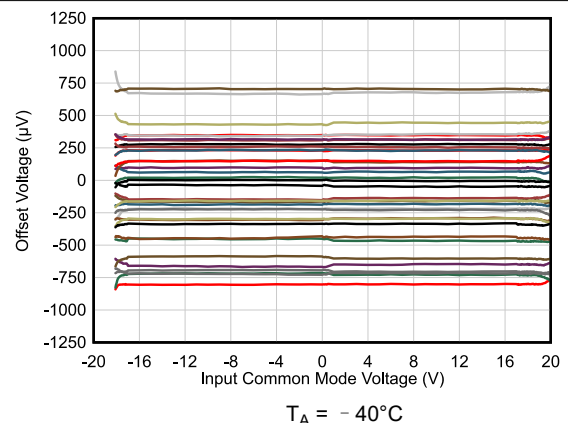


图 5-6. Offset Voltage vs Common-Mode Voltage

5.10 Typical Characteristics: TL08xH (continued)

at $T_A = 25^\circ\text{C}$, $V_S = 40\text{V}$ ($\pm 20\text{V}$), $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{k}\Omega$ connected to $V_S / 2$, and $C_L = 20\text{pF}$ (unless otherwise noted)

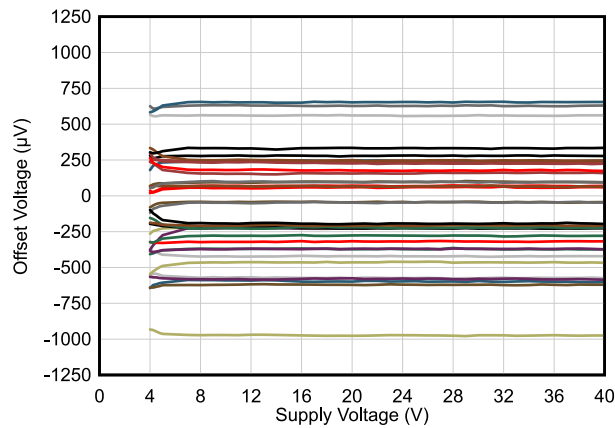


图 5-7. Offset Voltage vs Power Supply

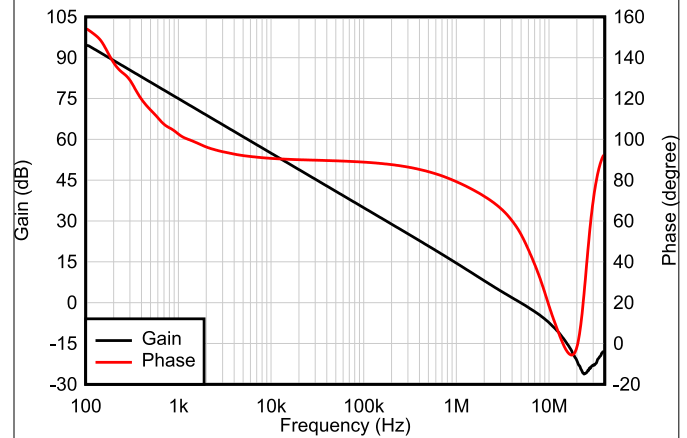


图 5-8. Open-Loop Gain and Phase vs Frequency

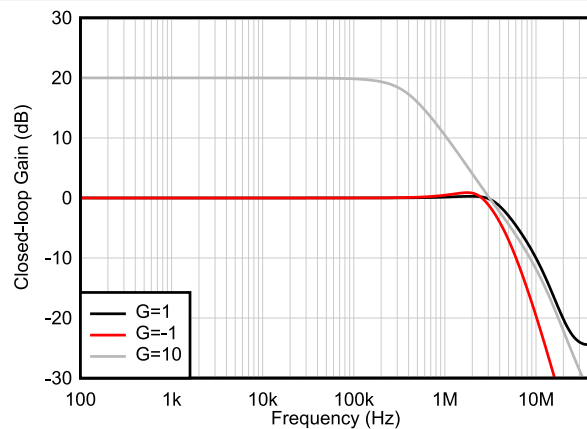


图 5-9. Closed-Loop Gain vs Frequency

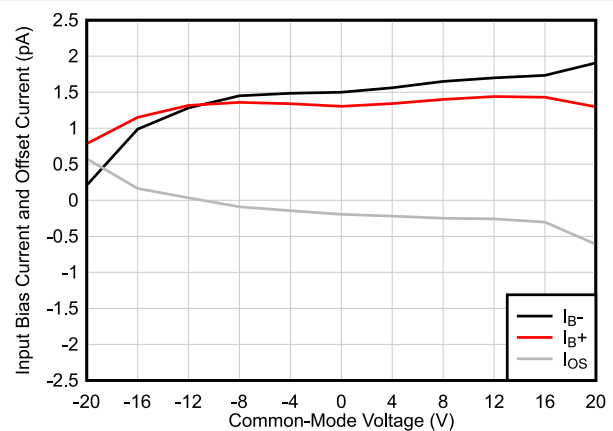


图 5-10. Input Bias Current vs Common-Mode Voltage

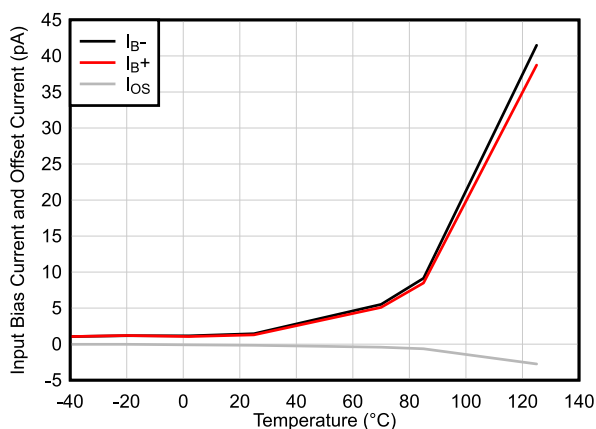


图 5-11. Input Bias Current vs Temperature

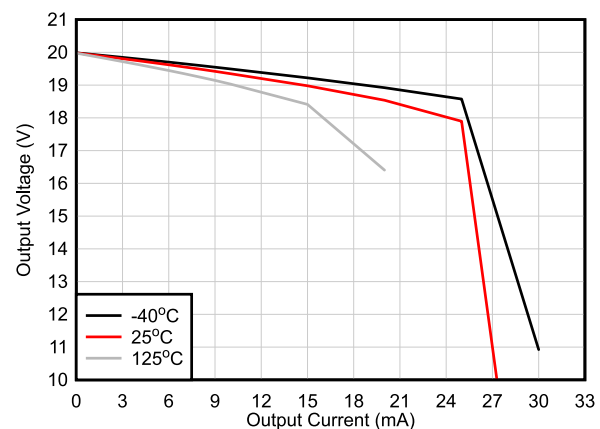


图 5-12. Output Voltage Swing vs Output Current (Sourcing)

5.10 Typical Characteristics: TL08xH (continued)

at $T_A = 25^\circ\text{C}$, $V_S = 40\text{V}$ ($\pm 20\text{V}$), $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{k}\Omega$ connected to $V_S / 2$, and $C_L = 20\text{pF}$ (unless otherwise noted)

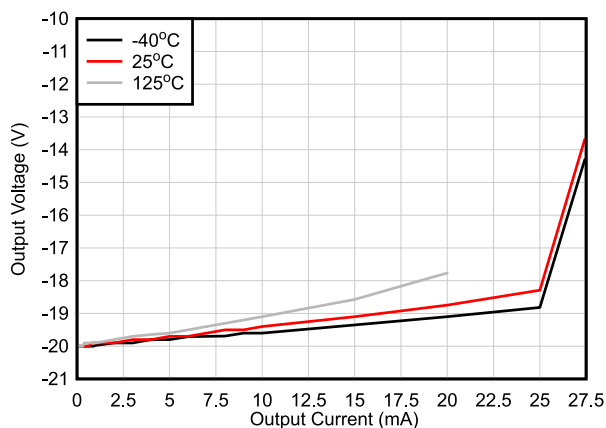


图 5-13. Output Voltage Swing vs Output Current (Sinking)

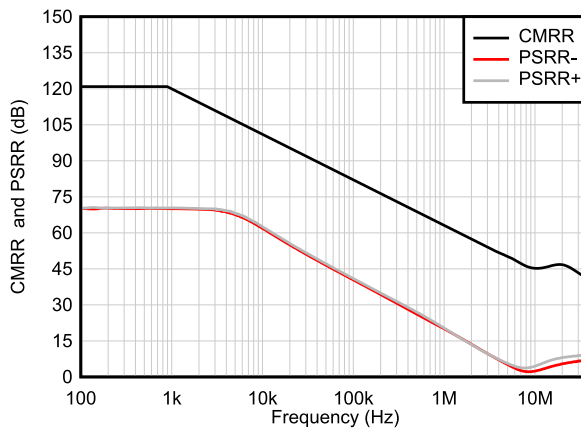


图 5-14. CMRR and PSRR vs Frequency

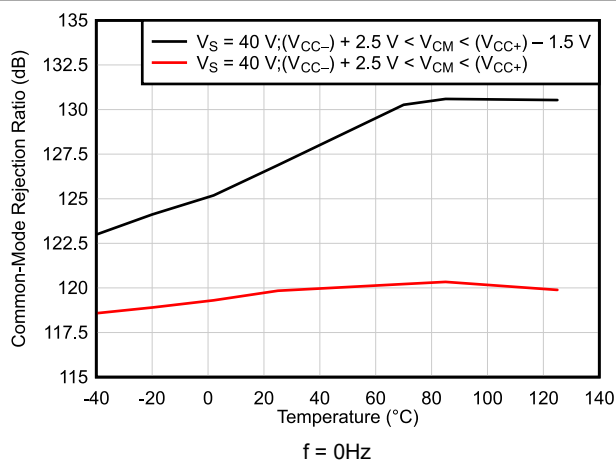


图 5-15. CMRR vs Temperature (dB)

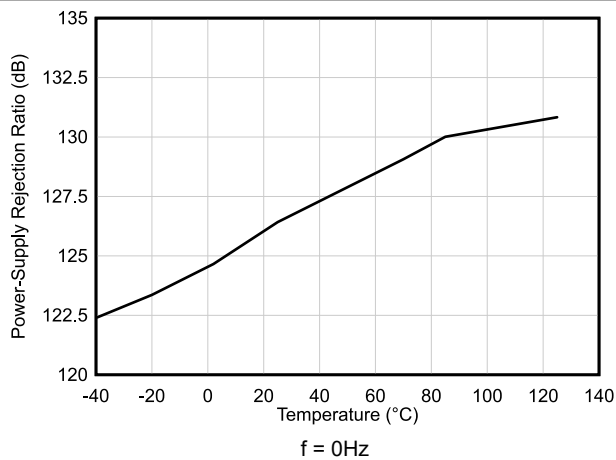


图 5-16. PSRR vs Temperature (dB)

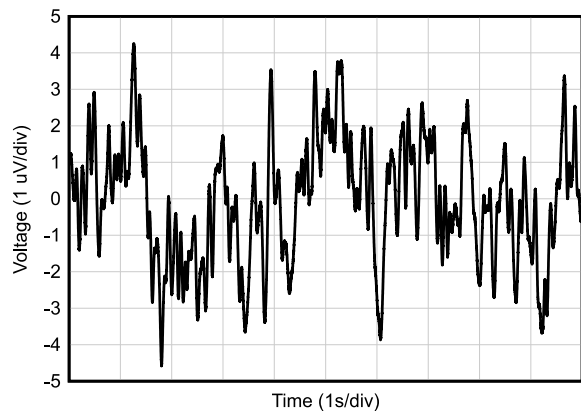


图 5-17. 0.1-Hz to 10-Hz Noise

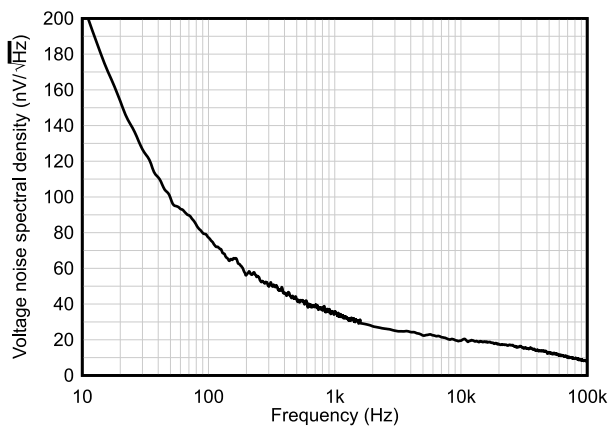


图 5-18. Input Voltage Noise Spectral Density vs Frequency

5.10 Typical Characteristics: TL08xH (continued)

at $T_A = 25^\circ\text{C}$, $V_S = 40\text{V}$ ($\pm 20\text{V}$), $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{k}\Omega$ connected to $V_S / 2$, and $C_L = 20\text{pF}$ (unless otherwise noted)

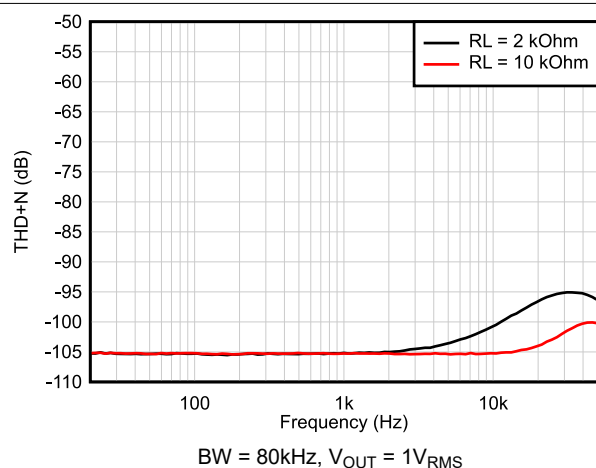


图 5-19. THD+N Ratio vs Frequency

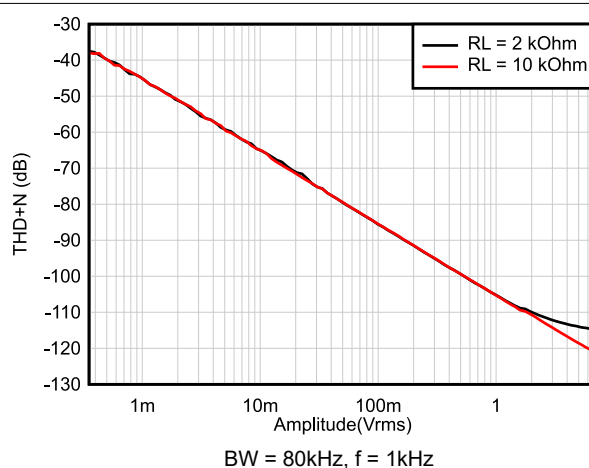


图 5-20. THD+N vs Output Amplitude

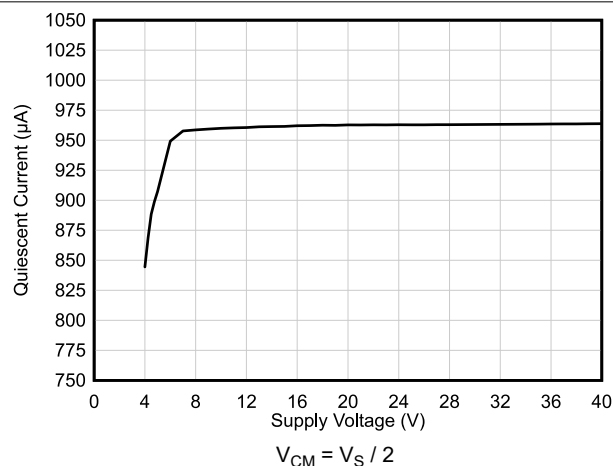


图 5-21. Quiescent Current vs Supply Voltage

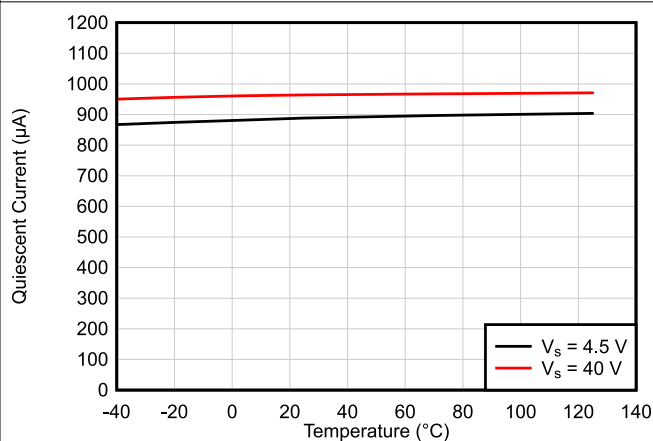


图 5-22. Quiescent Current vs Temperature

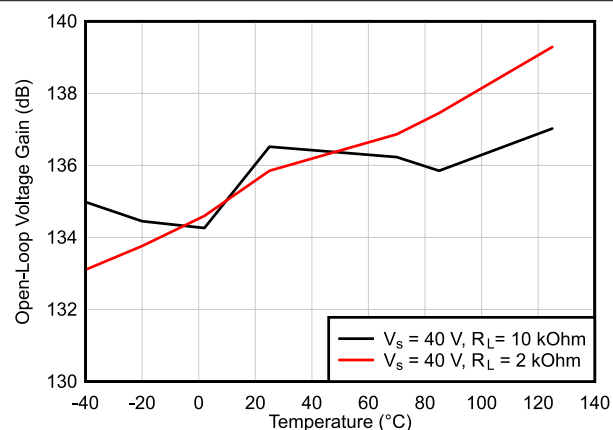


图 5-23. Open-Loop Voltage Gain vs Temperature (dB)

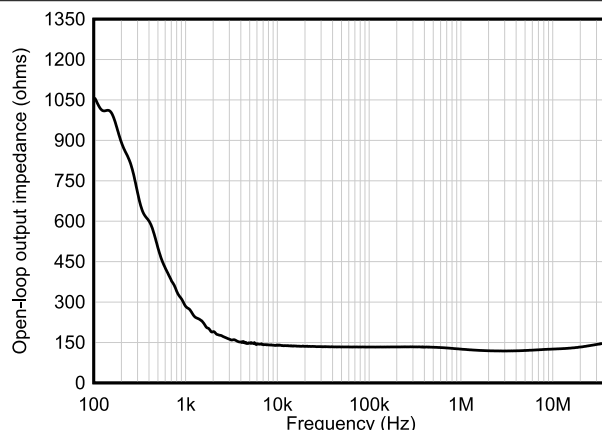
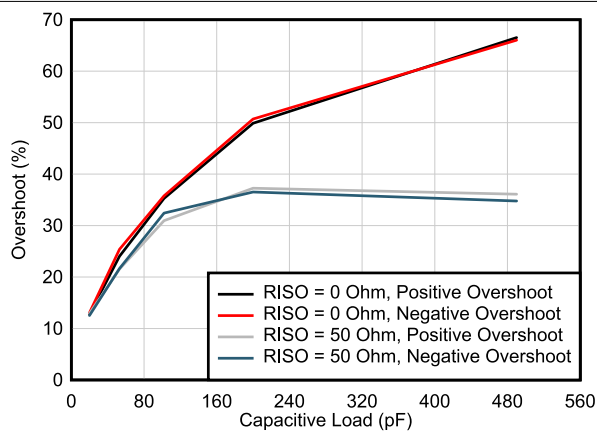


图 5-24. Open-Loop Output Impedance vs Frequency

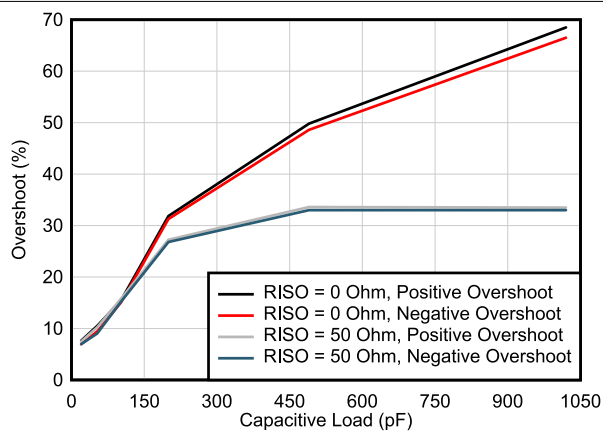
5.10 Typical Characteristics: TL08xH (continued)

at $T_A = 25^\circ\text{C}$, $V_S = 40\text{V}$ ($\pm 20\text{V}$), $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{k}\Omega$ connected to $V_S / 2$, and $C_L = 20\text{pF}$ (unless otherwise noted)



$G = -1$, 25-mV output step

图 5-25. Small-Signal Overshoot vs Capacitive Load



$G = 1$, 10-mV output step

图 5-26. Small-Signal Overshoot vs Capacitive Load

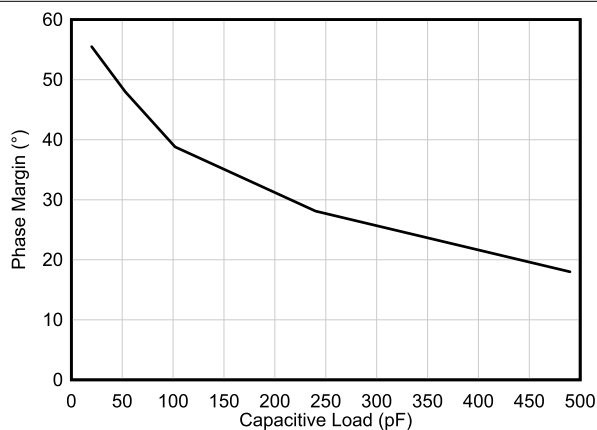
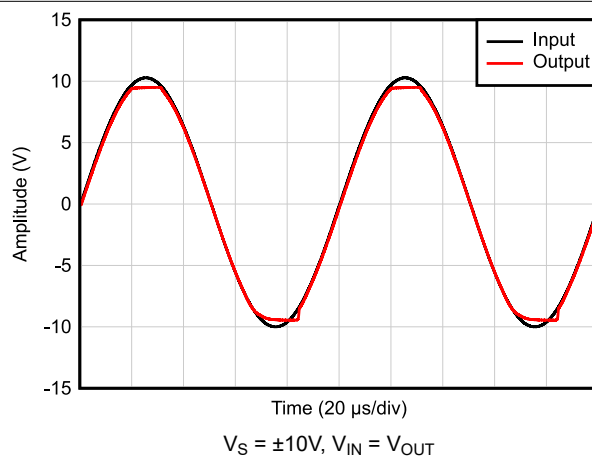
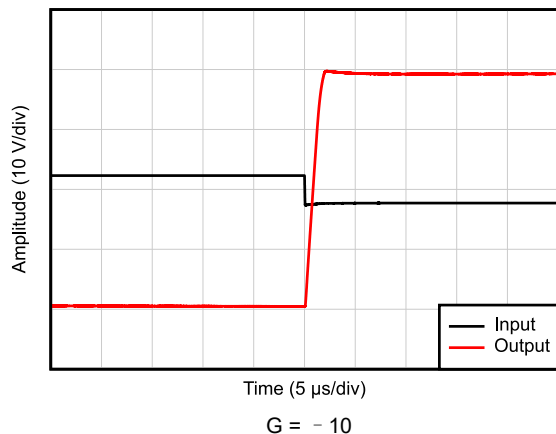


图 5-27. Phase Margin vs Capacitive Load



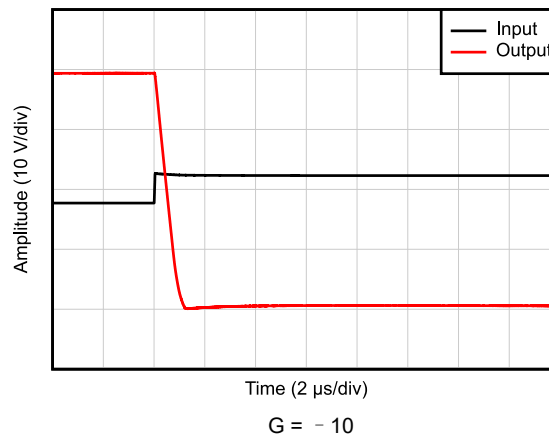
$V_S = \pm 10\text{V}$, $V_{IN} = V_{OUT}$

图 5-28. No Phase Reversal



$G = -10$

图 5-29. Positive Overload Recovery

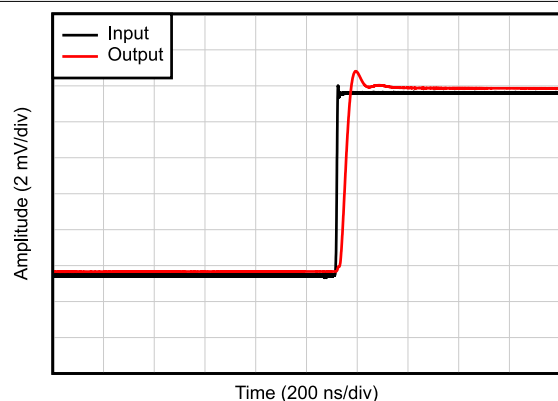


$G = -10$

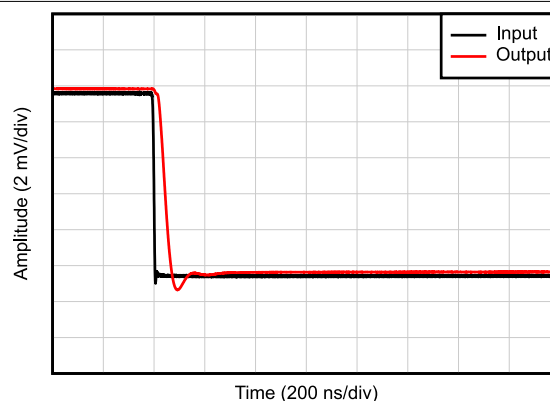
图 5-30. Negative Overload Recovery

5.10 Typical Characteristics: TL08xH (continued)

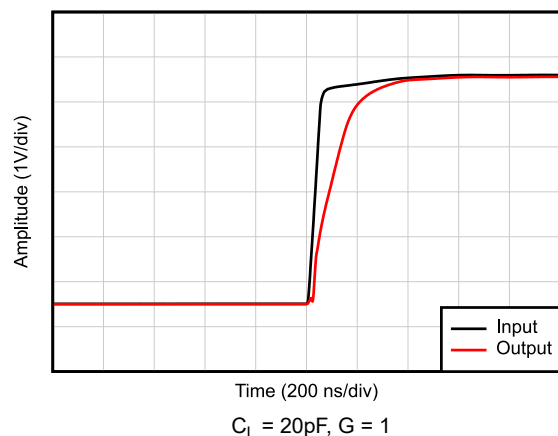
at $T_A = 25^\circ\text{C}$, $V_S = 40\text{V}$ ($\pm 20\text{V}$), $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{k}\Omega$ connected to $V_S / 2$, and $C_L = 20\text{pF}$ (unless otherwise noted)



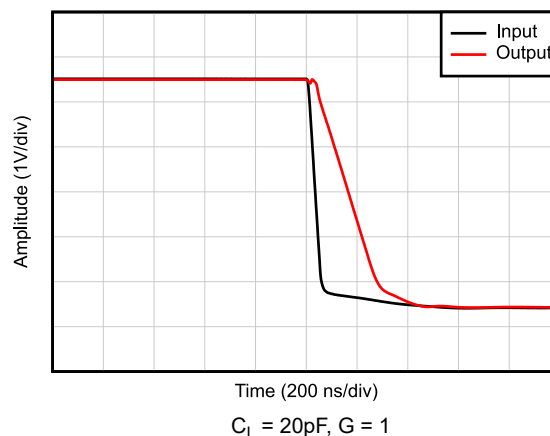
$C_L = 20\text{pF}$, $G = 1$, 10-mV step response
 图 5-31. Small-Signal Step Response, Rising



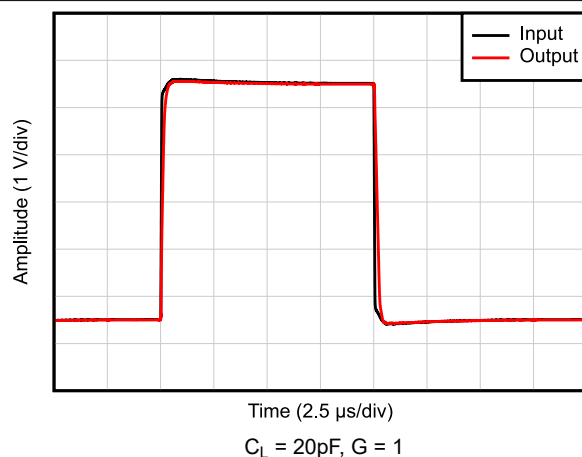
$C_L = 20\text{pF}$, $G = 1$, 10-mV step response
 图 5-32. Small-Signal Step Response, Falling



$C_L = 20\text{pF}$, $G = 1$
 图 5-33. Large-Signal Step Response (Rising)



$C_L = 20\text{pF}$, $G = 1$
 图 5-34. Large-Signal Step Response (Falling)



$C_L = 20\text{pF}$, $G = 1$
 图 5-35. Large-Signal Step Response

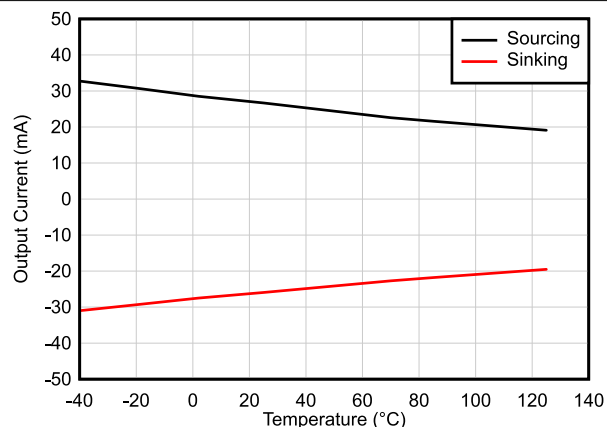


图 5-36. Short-Circuit Current vs Temperature

5.10 Typical Characteristics: TL08xH (continued)

at $T_A = 25^\circ\text{C}$, $V_S = 40\text{V}$ ($\pm 20\text{V}$), $V_{CM} = V_S / 2$, $R_{LOAD} = 10\text{k}\Omega$ connected to $V_S / 2$, and $C_L = 20\text{pF}$ (unless otherwise noted)

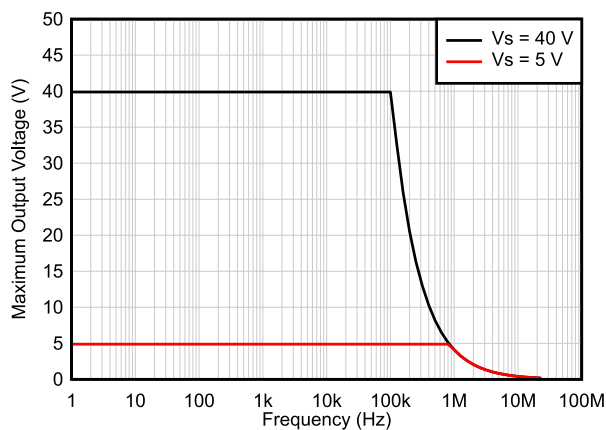


图 5-37. Maximum Output Voltage vs Frequency

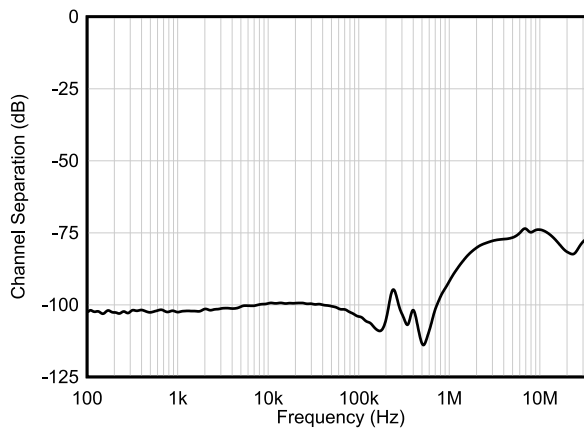


图 5-38. Channel Separation vs Frequency

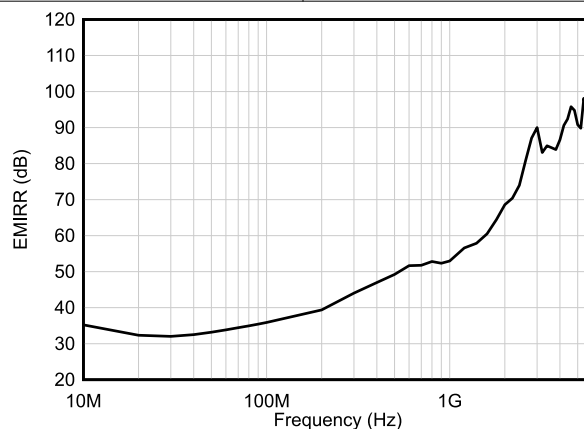


图 5-39. EMIRR (Electromagnetic Interference Rejection Ratio) vs Frequency

6 Parameter Measurement Information

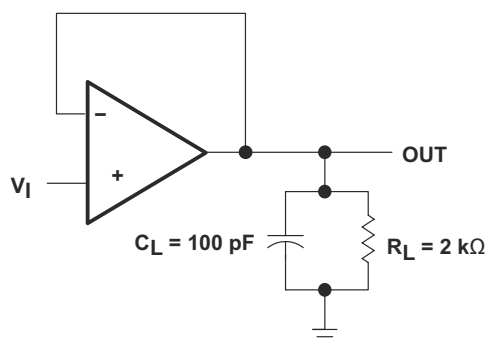


图 6-1. Test Figure 1

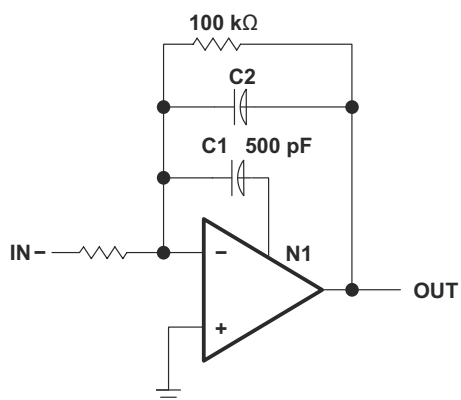


图 6-3. Test Figure 3

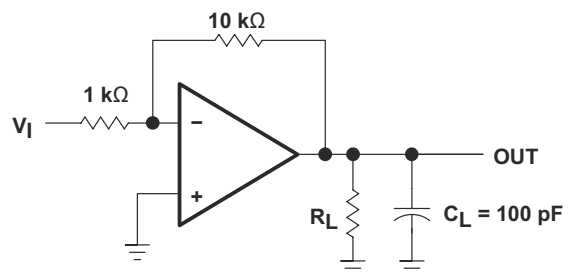


图 6-2. Test Figure 2

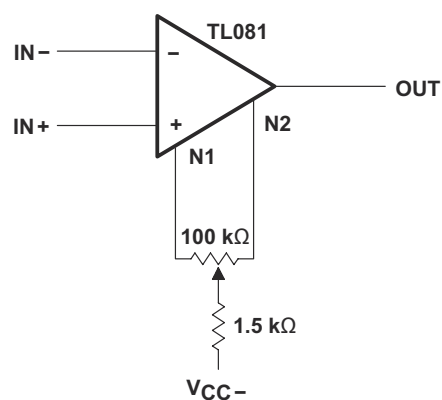


图 6-4. Test Figure 4

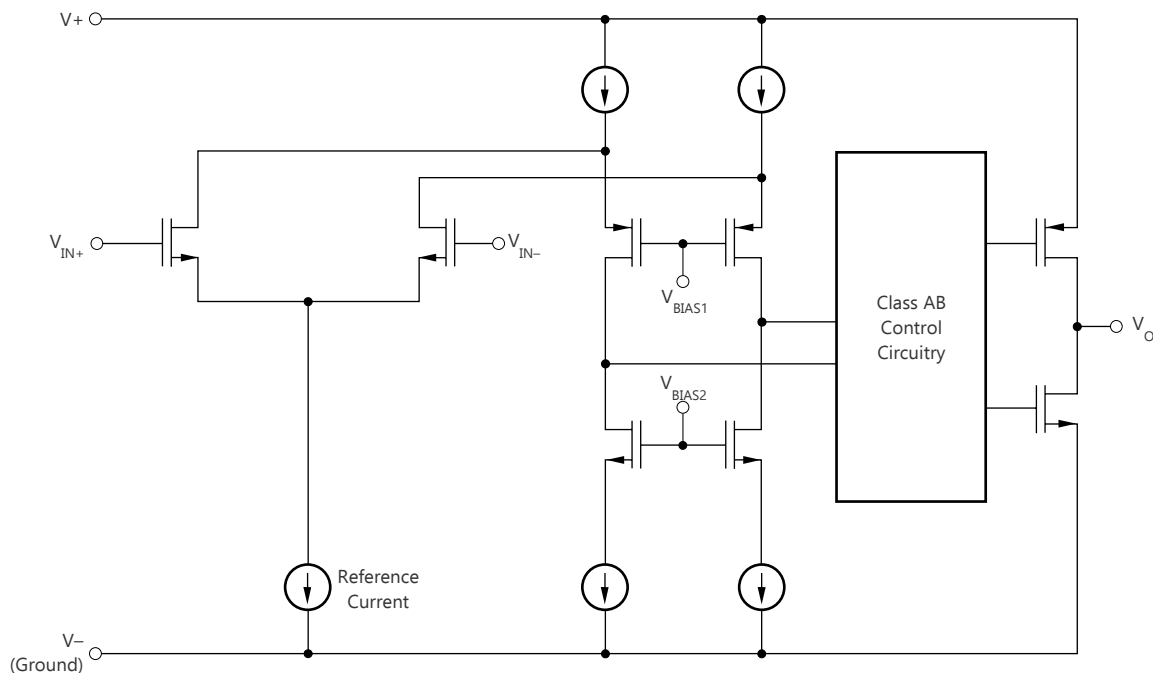
7 Detailed Description

7.1 Overview

The TL08xH family (TL081H, TL082H, and TL084H) is the next-generation family of the industry standard TL08x (TL081, TL082, and TL084) high-voltage general purpose amplifiers. These devices provide outstanding value for cost-sensitive applications requiring high slew rate with high voltage signals, such as motor drive and inverter systems.

A robust MUX-friendly input stage enhances flexibility in design, with common-mode voltage range extending to the positive rail as well as improved settling time in multi-channel applications. Low offset voltage (1mV, typ) and low offset voltage drift (2 μ V/°C) allows the TL08xH family to be used in rugged applications requiring precision current and voltage sensing. High voltage operation (up to 40V) and high slew rate (20V/ μ s) make the TL08xH family a premier choice for high-voltage applications with fast transients.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Total Harmonic Distortion

Harmonic distortions to an audio signal are created by electronic components in a circuit. Total harmonic distortion (THD) is a measure of harmonic distortions accumulated by a signal in an audio system. These devices have a very low THD of 0.003% meaning that the TL08x devices will add little harmonic distortion when used in audio signal applications.

7.3.2 Slew Rate

The slew rate is the rate at which an operational amplifier can change its output when there is a change on the input. These devices have a 20V/ μ s slew rate.

7.4 Device Functional Modes

These devices are powered on when the supply is connected. This device can be operated as a single-supply operational amplifier or dual-supply amplifier depending on the application.

8 Applications and Implementation

备注

以下应用部分中的信息不属于 TI 器件规格的范围，TI 不担保其准确性和完整性。TI 的客户应负责确定器件是否适用于其应用。客户应验证并测试其设计，以确保系统功能。

8.1 Application Information

The TL08x series of operational amplifiers can be used in countless applications. The few applications in this section show principles used in all applications of these parts.

8.2 Typical Applications

8.2.1 Inverting Amplifier Application

A typical application for an operational amplifier in an inverting amplifier. This amplifier takes a positive voltage on the input, and makes it a negative voltage of the same magnitude. In the same manner, it also makes negative voltages positive.

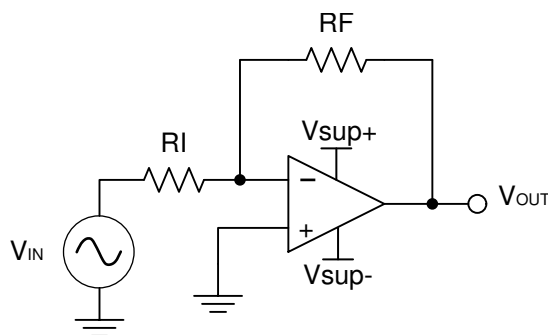


图 8-1. Schematic for Inverting Amplifier Application

8.2.1.1 Design Requirements

The supply voltage must be chosen such that it is larger than the input voltage range and output range. For instance, this application will scale a signal of $\pm 0.5\text{V}$ to $\pm 1.8\text{V}$. Setting the supply at $\pm 12\text{V}$ is sufficient to accommodate this application.

8.2.1.2 Detailed Design Procedure

Determine the gain required by the inverting amplifier:

$$A_V = \frac{V_{OUT}}{V_{IN}} \quad (1)$$

$$A_V = \frac{1.8}{-0.5} = -3.6 \quad (2)$$

Once the desired gain is determined, choose a value for R_I or R_F . Choosing a value in the $k\Omega$ range is desirable because the amplifier circuit will use currents in the milliamp range. This causes the part will not draw too much current. This example will choose $10k\Omega$ for R_I which means $36k\Omega$ will be used for R_F . This was determined by Equation 3.

$$A_V = -\frac{R_F}{R_I} \quad (3)$$

8.2.1.3 Application Curve

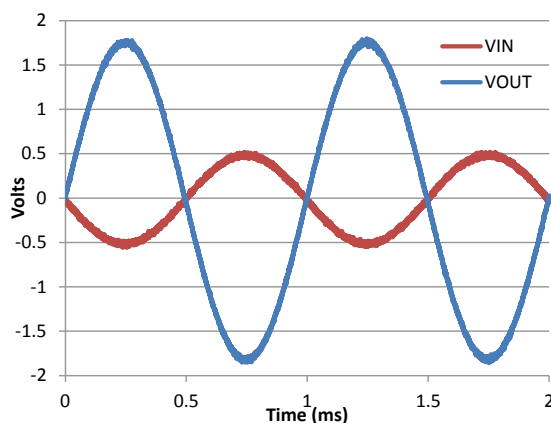


图 8-2. Input and Output Voltages of the Inverting Amplifier

8.3 System Examples

8.3.1 General Applications

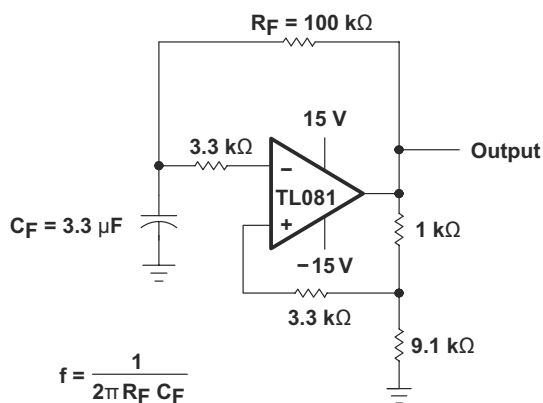


图 8-3. 0.5-Hz Square-Wave Oscillator

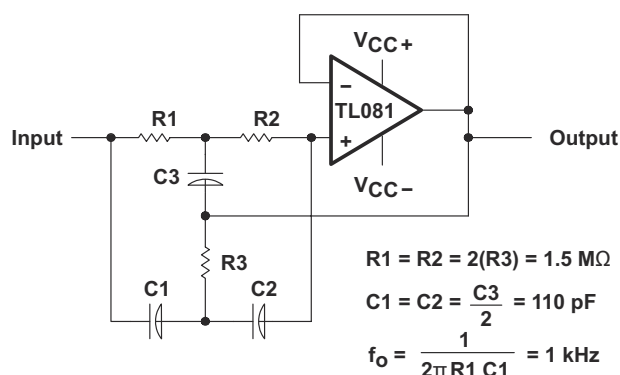


图 8-4. High-Q Notch Filter

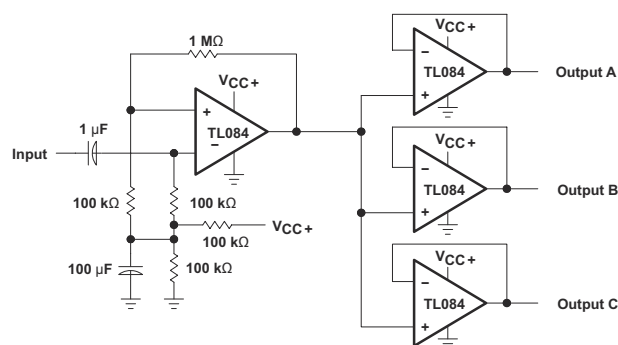


图 8-5. Audio-Distribution Amplifier

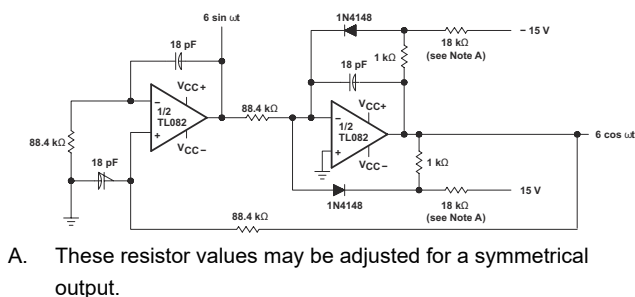


图 8-6. 100-kHz Quadrature Oscillator

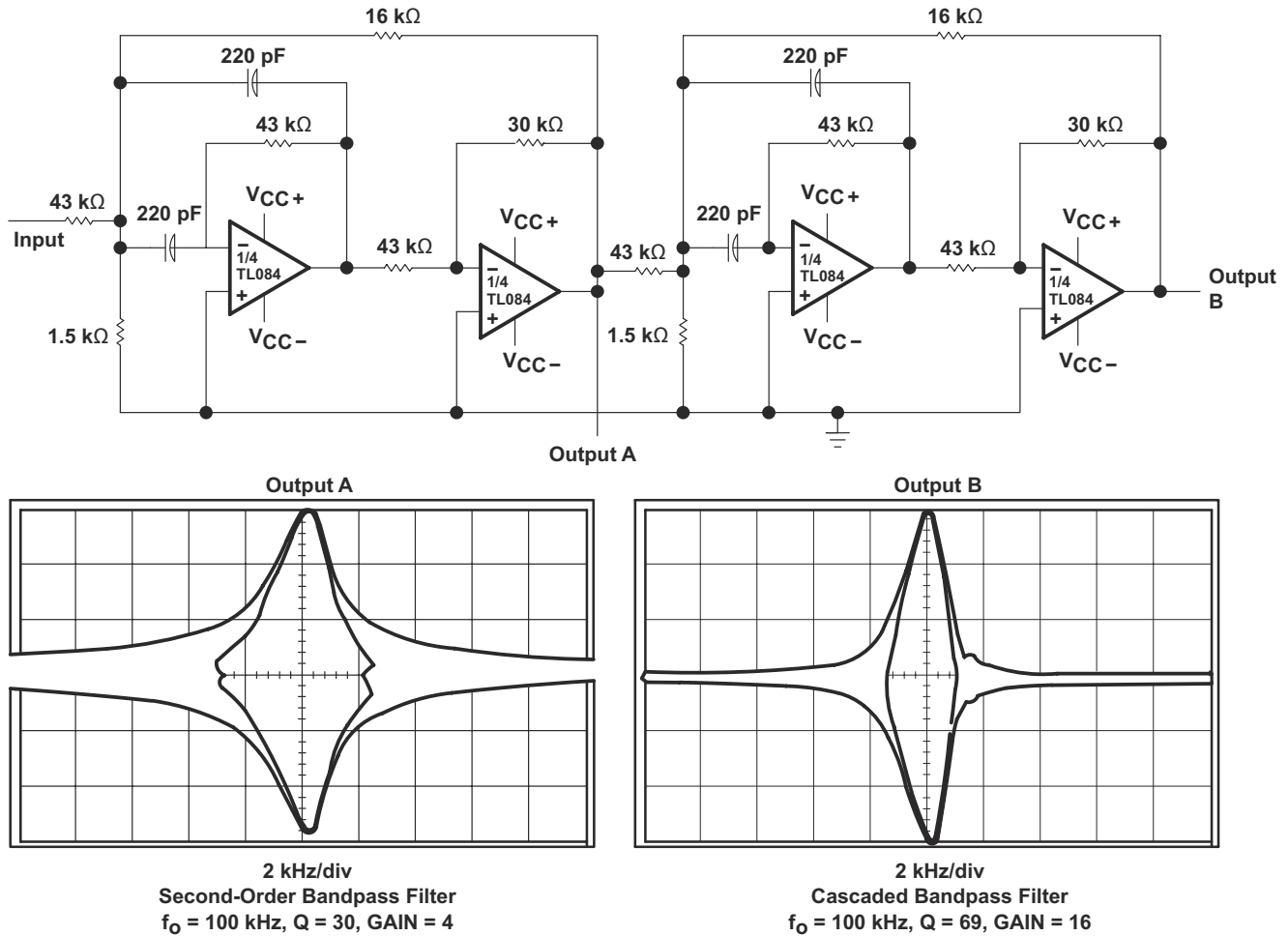


图 8-7. Positive-Feedback Bandpass Filter

8.4 Power Supply Recommendations

小心

Supply voltages larger than 36V for a single-supply or outside the range of $\pm 18\text{V}$ for a dual-supply can permanently damage the device (see 节 5.1).

Place $0.1 \mu\text{F}$ bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high impedance power supplies. For more detailed information on bypass capacitor placement, refer to 节 8.5.

8.5 Layout

8.5.1 Layout Guidelines

For best operational performance of the device, use good PCB layout practices, including:

- Noise can propagate into analog circuitry through the power pins of the circuit as a whole, as well as the operational amplifier. Bypass capacitors are used to reduce the coupled noise by providing low impedance power sources local to the analog circuitry.
 - Connect low-ESR, $0.1 \mu\text{F}$ ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from $V+$ to ground is applicable for single-supply applications.

- Separate grounding for analog and digital portions of circuitry is one of the simplest and most-effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces EMI noise pickup. Ensure to physically separate digital and analog grounds, paying attention to the flow of the ground current.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If it is not possible to keep them separate, it is much better to cross the sensitive trace perpendicular as opposed to in parallel with the noisy trace.
- Place the external components as close to the device as possible. Keeping RF and RG close to the inverting input minimizes parasitic capacitance, as shown in 节 8.5.2.
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

8.5.2 Layout Examples

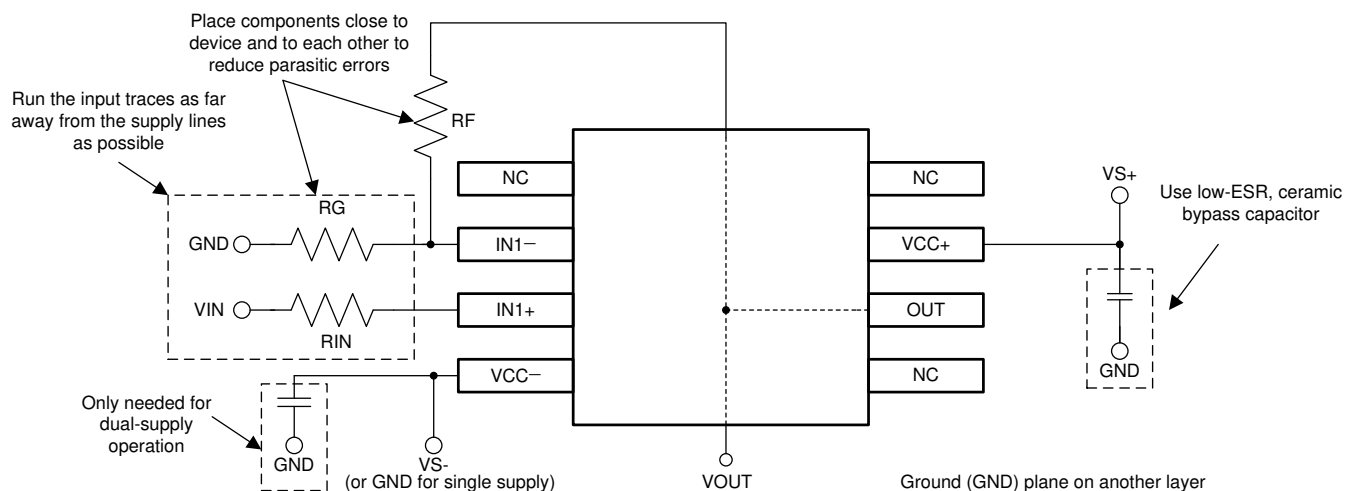


图 8-8. Operational Amplifier Board Layout for Noninverting Configuration

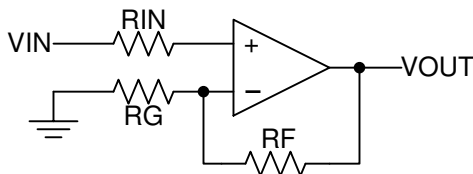


图 8-9. Operational Amplifier Schematic for Noninverting Configuration

9 Device and Documentation Support

9.1 接收文档更新通知

要接收文档更新通知，请导航至 [ti.com](https://www.ti.com) 上的器件产品文件夹。点击 [通知](#) 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

9.2 支持资源

[TI E2E™ 中文支持论坛](#) 是工程师的重要参考资料，可直接从专家处获得快速、经过验证的解答和设计帮助。搜索现有解答或提出自己的问题，获得所需的快速设计帮助。

链接的内容由各个贡献者“按原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 [使用条款](#)。

9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.
所有商标均为其各自所有者的财产。

9.4 静电放电警告



静电放电 (ESD) 会损坏这个集成电路。德州仪器 (TI) 建议通过适当的预防措施处理所有集成电路。如果不遵守正确的处理和安装程序，可能会损坏集成电路。

ESD 的损坏小至导致微小的性能降级，大至整个器件故障。精密的集成电路可能更容易受到损坏，这是因为非常细微的参数更改都可能会导致器件与其发布的规格不相符。

9.5 术语表

[TI 术语表](#) 本术语表列出并解释了术语、首字母缩略词和定义。

10 Revision History

注：以前版本的页码可能与当前版本的页码不同

Changes from Revision M (December 2021) to Revision N (June 2024)	Page
• Changed Absolute Maximum Ratings, ESD Ratings, Recommended Operating Conditions, and Thermal Information sections by merging TL08xH and TL08xx specifications.....	9
• Changed Electrical Characteristics tables by merging TL08xC, TL08xAC, TL08xBC, TL08xI, and TL08xM specifications.....	14
• Increased gain bandwidth of all non-NS/non-PS packages and non-TL08xM devices from 3MHz to 5.25MHz.....	14
• Merged TL08xC, TL08xAC, TL08xBC, TL08xI, and TL08xM Switching Characteristics tables and renamed to Electrical Characteristics (AC).....	16
• Changed input voltage noise density at 1kHz for all non-PS/non-NS packages and all non-TL08xM devices to 37nV/√Hz.....	16
• Changed THD+N for all non-PS/non-NS packages and all non-TL08xM devices to 0.00012%.....	16
• Updated <i>Functional Block Diagram</i> and <i>Feature Description</i> sections.....	25

Changes from Revision L (July 2021) to Revision M (December 2021)	Page
• Corrected DCK pinout diagram and table in <i>Pin Configurations and Functions</i> section.....	3

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
5962-9851501Q2A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9851501Q2A TL082MFKB
5962-9851501QPA	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9851501QPA TL082M
5962-9851503Q2A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9851503Q2A TL084 MFKB
5962-9851503QCA	Active	Production	CDIP (J) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9851503QC A TL084MJB
TL081ACD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	0 to 70	081AC
TL081ACDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	081AC
TL081ACDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	081AC
TL081ACP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL081ACP
TL081ACP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL081ACP
TL081BCD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	0 to 70	081BC
TL081BCDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	081BC
TL081BCDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	081BC
TL081BCP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL081BCP
TL081BCP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL081BCP
TL081CD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	0 to 70	TL081C
TL081CDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL081C
TL081CDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL081C
TL081CP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL081CP
TL081CP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL081CP
TL081CPE4	Active	Production	PDIP (P) 8	50 TUBE	-	Call TI	Call TI	0 to 70	
TL081CPSR	Active	Production	SO (PS) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	T081
TL081CPSR.A	Active	Production	SO (PS) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	T081
TL081HIDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	T81V

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TL081HIDBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T81V
TL081HIDBVR.B	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T81V
TL081HIDCKR	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1IP
TL081HIDCKR.A	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	1IP
TL081HIDR	Active	Production	SOIC (D) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL081D
TL081HIDR.A	Active	Production	SOIC (D) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL081D
TL081HIDR.B	Active	Production	SOIC (D) 8	3000 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TL081ID	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	-40 to 85	TL081I
TL081IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL081I
TL081IDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL081I
TL081IP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TL081IP
TL081IP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TL081IP
TL082ACD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	0 to 70	082AC
TL082ACDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	082AC
TL082ACDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	082AC
TL082ACDRE4	Active	Production	SOIC (D) 8	2500 LARGE T&R	-	Call TI	Call TI	0 to 70	
TL082ACP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL082ACP
TL082ACP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL082ACP
TL082ACPSR	Active	Production	SO (PS) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	T082A
TL082ACPSR.A	Active	Production	SO (PS) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	T082A
TL082BCD	Obsolete	Production	SOIC (D) 8	-	-	Call TI	Call TI	0 to 70	082BC
TL082BCDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	082BC
TL082BCDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	082BC
TL082BCDRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	082BC
TL082BCDRG4.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	082BC
TL082BCP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL082BCP
TL082BCP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL082BCP
TL082BCPE4	Active	Production	PDIP (P) 8	50 TUBE	-	Call TI	Call TI	0 to 70	
TL082CDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL082C
TL082CDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL082C
TL082CDRE4	Active	Production	SOIC (D) 8	2500 LARGE T&R	-	Call TI	Call TI	0 to 70	

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TL082CDRG4	Active	Production	SOIC (D) 8	2500 LARGE T&R	-	Call TI	Call TI	0 to 70	
TL082CP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL082CP
TL082CP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL082CP
TL082CPSR	Active	Production	SO (PS) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	T082
TL082CPSR.A	Active	Production	SO (PS) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	T082
TL082CPSRG4	Active	Production	SO (PS) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	T082
TL082CPWR	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	T082
TL082CPWR.A	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	T082
TL082CPWRG4	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	-	Call TI	Call TI	0 to 70	
TL082HIDDFR	Active	Production	SOT-23-THIN (DDF) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	082F
TL082HIDDFR.A	Active	Production	SOT-23-THIN (DDF) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	082F
TL082HIDDFR.B	Active	Production	SOT-23-THIN (DDF) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	082F
TL082HIDR	Active	Production	SOIC (D) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL082D
TL082HIDR.A	Active	Production	SOIC (D) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL082D
TL082HIPWR	Active	Production	TSSOP (PW) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	082HPW
TL082HIPWR.A	Active	Production	TSSOP (PW) 8	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	082HPW
TL082IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL082I
TL082IDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL082I
TL082IDRE4	Active	Production	SOIC (D) 8	2500 LARGE T&R	-	Call TI	Call TI	-40 to 85	
TL082IP	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TL082IP
TL082IP.A	Active	Production	PDIP (P) 8	50 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TL082IP
TL082IPE4	Active	Production	PDIP (P) 8	50 TUBE	-	Call TI	Call TI	-40 to 85	
TL082IPWR	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	Z082
TL082IPWR.A	Active	Production	TSSOP (PW) 8	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	Z082
TL082MFKB	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9851501Q2A TL082MFKB
TL082MFKB.A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9851501Q2A TL082MFKB
TL082MJG	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	TL082MJG
TL082MJG.A	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	TL082MJG

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TL082MJGB	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9851501QPA TL082M
TL082MJGB.A	Active	Production	CDIP (JG) 8	50 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	9851501QPA TL082M
TL084ACDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL084AC
TL084ACDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL084AC
TL084ACN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL084ACN
TL084ACN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL084ACN
TL084ACNSR	Active	Production	SOP (NS) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL084A
TL084ACNSR.A	Active	Production	SOP (NS) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL084A
TL084BCDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL084BC
TL084BCDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL084BC
TL084BCDR.B	Active	Production	SOIC (D) 14	2500 LARGE T&R	-	Call TI	Call TI	0 to 70	
TL084BCDR1G4	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL084BC
TL084BCDR1G4.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL084BC
TL084BCDRG4	Active	Production	SOIC (D) 14	2500 LARGE T&R	-	Call TI	Call TI	0 to 70	
TL084BCN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL084BCN
TL084BCN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL084BCN
TL084BCNE4	Active	Production	PDIP (N) 14	25 TUBE	-	Call TI	Call TI	0 to 70	
TL084CDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL084C
TL084CDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL084C
TL084CDRG4	Obsolete	Production	SOIC (D) 14	-	-	Call TI	Call TI	0 to 70	TL084C
TL084CN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL084CN
TL084CN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	0 to 70	TL084CN
TL084CNSR	Active	Production	SOP (NS) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL084
TL084CNSR.A	Active	Production	SOP (NS) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL084
TL084CPWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	0 to 70	T084
TL084CPWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	T084
TL084CPWRG4	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	0 to 70	T084
TL084HIDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL084HID
TL084HIDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL084HID

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TL084HIDYYR	Active	Production	SOT-23-THIN (DYY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T084HDYY
TL084HIDYYR.A	Active	Production	SOT-23-THIN (DYY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T084HDYY
TL084HIDYYR.B	Active	Production	SOT-23-THIN (DYY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T084HDYY
TL084HIDYYRG4	Active	Production	SOT-23-THIN (DYY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T084HDYY
TL084HIDYYRG4.A	Active	Production	SOT-23-THIN (DYY) 14	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T084HDYY
TL084HIPWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 125	TL084PW
TL084HIPWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL084PW
TL084IDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL084I
TL084IDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	TL084I
TL084IDR.B	Active	Production	SOIC (D) 14	2500 LARGE T&R	-	Call TI	Call TI	-40 to 125	
TL084IDR1G4	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL084I
TL084IDR1G4.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL084I
TL084IDRE4	Active	Production	SOIC (D) 14	2500 LARGE T&R	-	Call TI	Call TI	-40 to 85	
TL084IDRG4	Active	Production	SOIC (D) 14	2500 LARGE T&R	-	Call TI	Call TI	-40 to 85	
TL084IN	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TL084IN
TL084IN.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	TL084IN
TL084ING4	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TL084IN
TL084ING4.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 125	TL084IN
TL084MFK	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	TL084MFK
TL084MFK.A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	TL084MFK
TL084MFKB	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9851503Q2A TL084 MFKB
TL084MFKB.A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962- 9851503Q2A TL084 MFKB
TL084MJ	Active	Production	CDIP (J) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	TL084MJ

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TL084MJ.A	Active	Production	CDIP (J) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	TL084MJ
TL084MJB	Active	Production	CDIP (J) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9851503QC A TL084MJB
TL084MJB.A	Active	Production	CDIP (J) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-9851503QC A TL084MJB
TL084QDR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL084Q
TL084QDR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL084Q
TL084QDRG4	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL084Q
TL084QDRG4.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	TL084Q

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TL082, TL082M, TL084, TL084M :

- Catalog : [TL082](#), [TL084](#)
- Automotive : [TL082-Q1](#), [TL082-Q1](#)
- Military : [TL082M](#), [TL084M](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Military - QML certified for Military and Defense Applications

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL081ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL081BCDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL081CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL081CPSR	SO	PS	8	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
TL081HIDBVR	SOT-23	DBV	5	3000	178.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TL081HIDCKR	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
TL081HIDR	SOIC	D	8	3000	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL081IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL082ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL082ACDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL082ACPSR	SO	PS	8	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
TL082BCDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL082BCDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL082CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL082CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL082CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL082CPSR	SO	PS	8	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
TL082CPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
TL082HIDDFR	SOT-23-THIN	DDF	8	3000	180.0	8.4	3.2	3.2	1.4	4.0	8.0	Q3
TL082HIDR	SOIC	D	8	3000	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL082HIPWR	TSSOP	PW	8	3000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
TL082IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL082IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL082IPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
TL084ACDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL084ACNSR	SOP	NS	14	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
TL084BCDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL084BCDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL084BCDR1G4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL084CDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL084CNSR	SOP	NS	14	2000	330.0	16.4	8.45	10.55	2.5	12.0	16.2	Q1
TL084CPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TL084CPWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TL084CPWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TL084HIDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL084HIDYYR	SOT-23-THIN	DYY	14	3000	330.0	12.4	4.8	3.6	1.6	8.0	12.0	Q3
TL084HIDYYRG4	SOT-23-THIN	DYY	14	3000	330.0	12.4	4.8	3.6	1.6	8.0	12.0	Q3
TL084HIPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
TL084IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL084IDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL084IDR1G4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL084QDR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
TL084QDRG4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1

TAPE AND REEL BOX DIMENSIONS

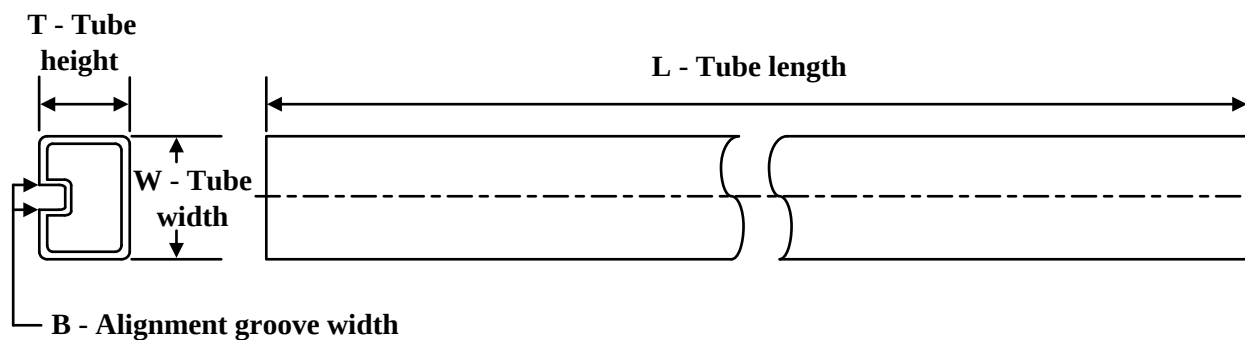


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL081ACDR	SOIC	D	8	2500	340.5	338.1	20.6
TL081BCDR	SOIC	D	8	2500	353.0	353.0	32.0
TL081CDR	SOIC	D	8	2500	340.5	338.1	20.6
TL081CPSR	SO	PS	8	2000	353.0	353.0	32.0
TL081HIDBVR	SOT-23	DBV	5	3000	208.0	191.0	35.0
TL081HIDCKR	SC70	DCK	5	3000	190.0	190.0	30.0
TL081HIDR	SOIC	D	8	3000	353.0	353.0	32.0
TL081IDR	SOIC	D	8	2500	353.0	353.0	32.0
TL082ACDR	SOIC	D	8	2500	353.0	353.0	32.0
TL082ACDR	SOIC	D	8	2500	340.5	338.1	20.6
TL082ACPSR	SO	PS	8	2000	353.0	353.0	32.0
TL082BCDR	SOIC	D	8	2500	353.0	353.0	32.0
TL082BCDRG4	SOIC	D	8	2500	353.0	353.0	32.0
TL082CDR	SOIC	D	8	2500	353.0	353.0	32.0
TL082CDR	SOIC	D	8	2500	353.0	353.0	32.0
TL082CDR	SOIC	D	8	2500	353.0	353.0	32.0
TL082CPSR	SO	PS	8	2000	353.0	353.0	32.0
TL082CPWR	TSSOP	PW	8	2000	353.0	353.0	32.0

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL082HIDDFR	SOT-23-THIN	DDF	8	3000	210.0	185.0	35.0
TL082HIDR	SOIC	D	8	3000	353.0	353.0	32.0
TL082HIPWR	TSSOP	PW	8	3000	353.0	353.0	32.0
TL082IDR	SOIC	D	8	2500	353.0	353.0	32.0
TL082IDR	SOIC	D	8	2500	353.0	353.0	32.0
TL082IPWR	TSSOP	PW	8	2000	353.0	353.0	32.0
TL084ACDR	SOIC	D	14	2500	353.0	353.0	32.0
TL084ACNSR	SOP	NS	14	2000	353.0	353.0	32.0
TL084BCDR	SOIC	D	14	2500	353.0	353.0	32.0
TL084BCDR	SOIC	D	14	2500	353.0	353.0	32.0
TL084BCDR1G4	SOIC	D	14	2500	353.0	353.0	32.0
TL084CDR	SOIC	D	14	2500	353.0	353.0	32.0
TL084CNSR	SOP	NS	14	2000	353.0	353.0	32.0
TL084CPWR	TSSOP	PW	14	2000	356.0	356.0	35.0
TL084CPWRG4	TSSOP	PW	14	2000	353.0	353.0	32.0
TL084CPWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0
TL084HIDR	SOIC	D	14	2500	353.0	353.0	32.0
TL084HIDYYR	SOT-23-THIN	DYY	14	3000	336.6	336.6	31.8
TL084HIDYYRG4	SOT-23-THIN	DYY	14	3000	336.6	336.6	31.8
TL084HIPWR	TSSOP	PW	14	2000	356.0	356.0	35.0
TL084IDR	SOIC	D	14	2500	353.0	353.0	32.0
TL084IDR	SOIC	D	14	2500	353.0	353.0	32.0
TL084IDR1G4	SOIC	D	14	2500	353.0	353.0	32.0
TL084QDR	SOIC	D	14	2500	353.0	353.0	32.0
TL084QDRG4	SOIC	D	14	2500	353.0	353.0	32.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
5962-9851501Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-9851503Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
TL081ACP	P	PDIP	8	50	506	13.97	11230	4.32
TL081ACP.A	P	PDIP	8	50	506	13.97	11230	4.32
TL081BCP	P	PDIP	8	50	506	13.97	11230	4.32
TL081BCP.A	P	PDIP	8	50	506	13.97	11230	4.32
TL081CP	P	PDIP	8	50	506	13.97	11230	4.32
TL081CP.A	P	PDIP	8	50	506	13.97	11230	4.32
TL081IP	P	PDIP	8	50	506	13.97	11230	4.32
TL081IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TL082ACP	P	PDIP	8	50	506	13.97	11230	4.32
TL082ACP.A	P	PDIP	8	50	506	13.97	11230	4.32
TL082BCP	P	PDIP	8	50	506	13.97	11230	4.32
TL082BCP.A	P	PDIP	8	50	506	13.97	11230	4.32
TL082CP	P	PDIP	8	50	506	13.97	11230	4.32
TL082CP.A	P	PDIP	8	50	506	13.97	11230	4.32
TL082IP	P	PDIP	8	50	506	13.97	11230	4.32
TL082IP	P	PDIP	8	50	506	13.97	11230	4.32
TL082IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TL082IP.A	P	PDIP	8	50	506	13.97	11230	4.32
TL082MFKB	FK	LCCC	20	55	506.98	12.06	2030	NA
TL082MFKB.A	FK	LCCC	20	55	506.98	12.06	2030	NA
TL084ACN	N	PDIP	14	25	506	13.97	11230	4.32
TL084ACN	N	PDIP	14	25	506	13.97	11230	4.32
TL084ACN.A	N	PDIP	14	25	506	13.97	11230	4.32
TL084ACN.A	N	PDIP	14	25	506	13.97	11230	4.32
TL084BCN	N	PDIP	14	25	506	13.97	11230	4.32
TL084BCN	N	PDIP	14	25	506	13.97	11230	4.32
TL084BCN.A	N	PDIP	14	25	506	13.97	11230	4.32

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
TL084BCN.A	N	PDIP	14	25	506	13.97	11230	4.32
TL084CN	N	PDIP	14	25	506	13.97	11230	4.32
TL084CN.A	N	PDIP	14	25	506	13.97	11230	4.32
TL084IN	N	PDIP	14	25	506	13.97	11230	4.32
TL084IN.A	N	PDIP	14	25	506	13.97	11230	4.32
TL084ING4	N	PDIP	14	25	506	13.97	11230	4.32
TL084ING4.A	N	PDIP	14	25	506	13.97	11230	4.32
TL084MFK	FK	LCCC	20	55	506.98	12.06	2030	NA
TL084MFK.A	FK	LCCC	20	55	506.98	12.06	2030	NA
TL084MFKB	FK	LCCC	20	55	506.98	12.06	2030	NA
TL084MFKB.A	FK	LCCC	20	55	506.98	12.06	2030	NA

GENERIC PACKAGE VIEW

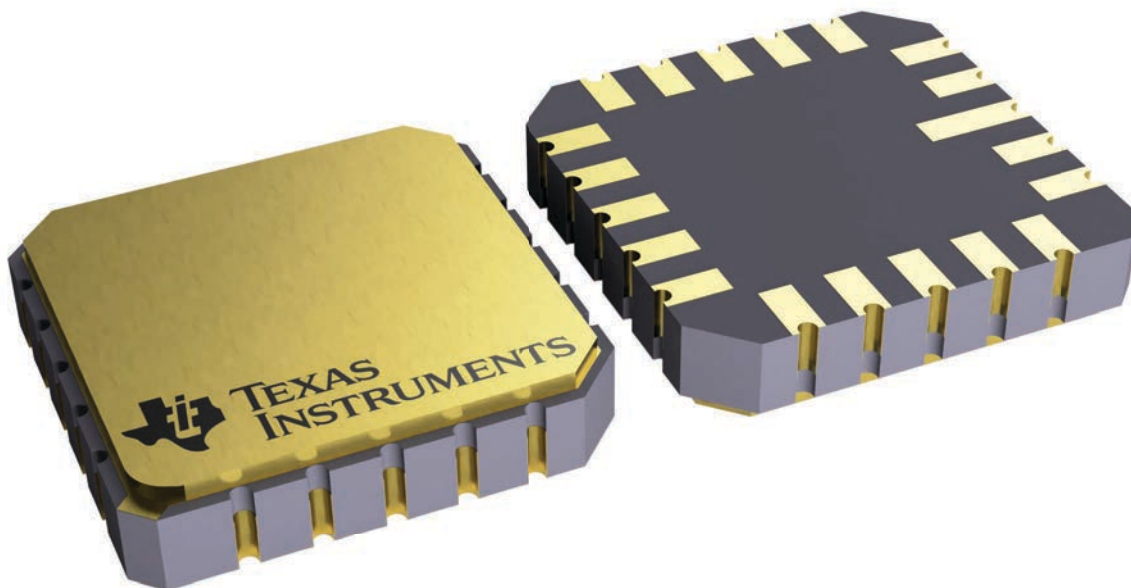
FK 20

LCCC - 2.03 mm max height

8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



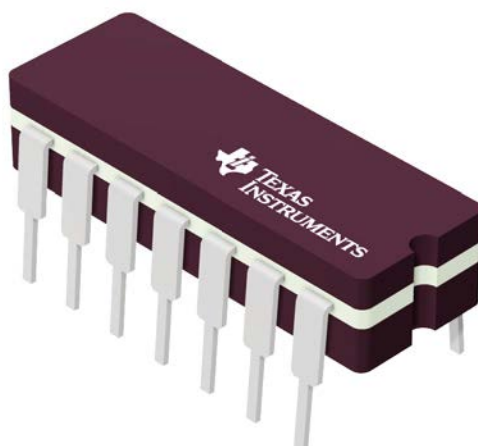
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J 14

GENERIC PACKAGE VIEW

CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4040083-5/G

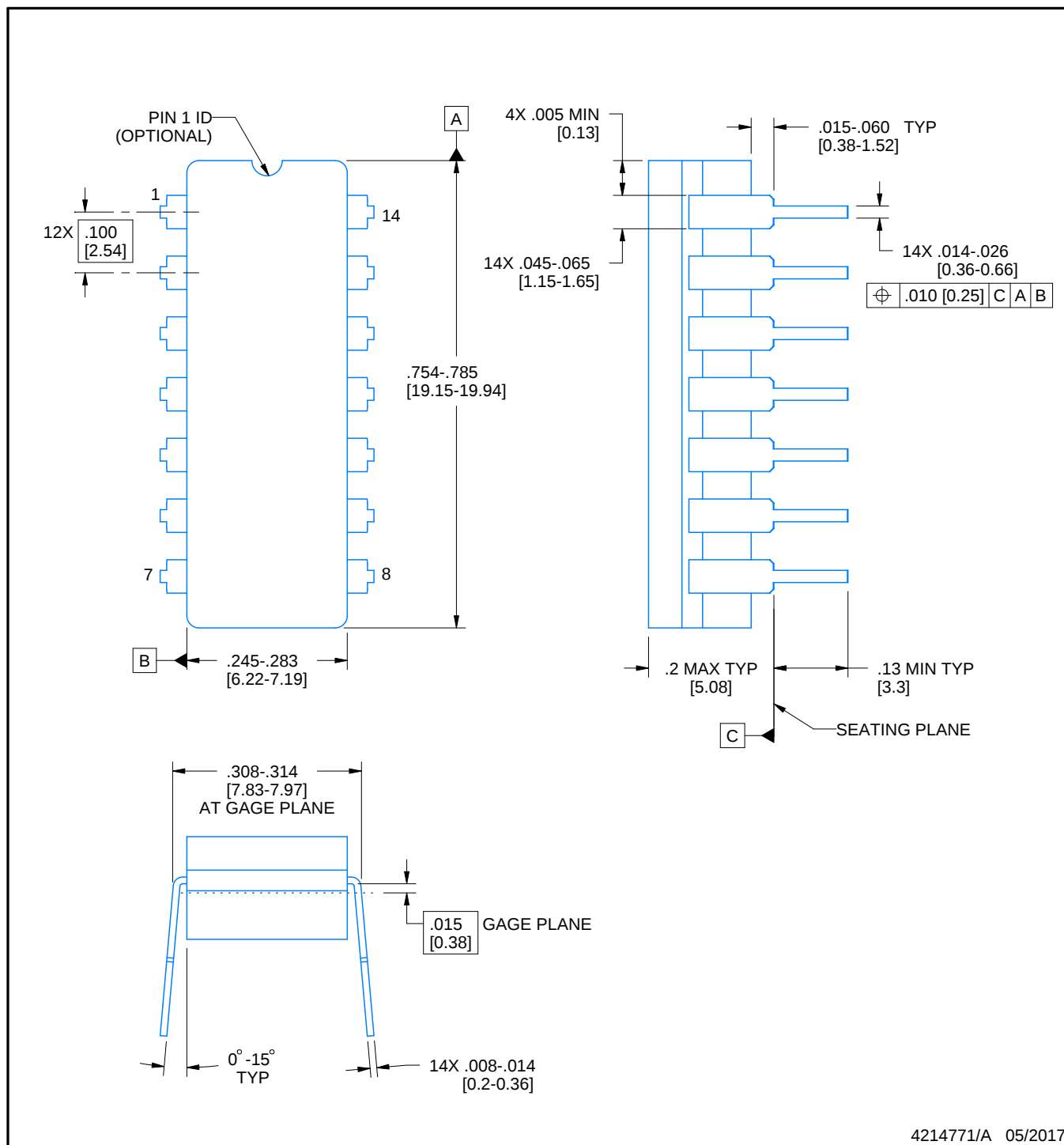


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PACKAGE OUTLINE

CDIP - 5.08 mm max height

CERAMIC DUAL IN LINE PACKAGE



NOTES:

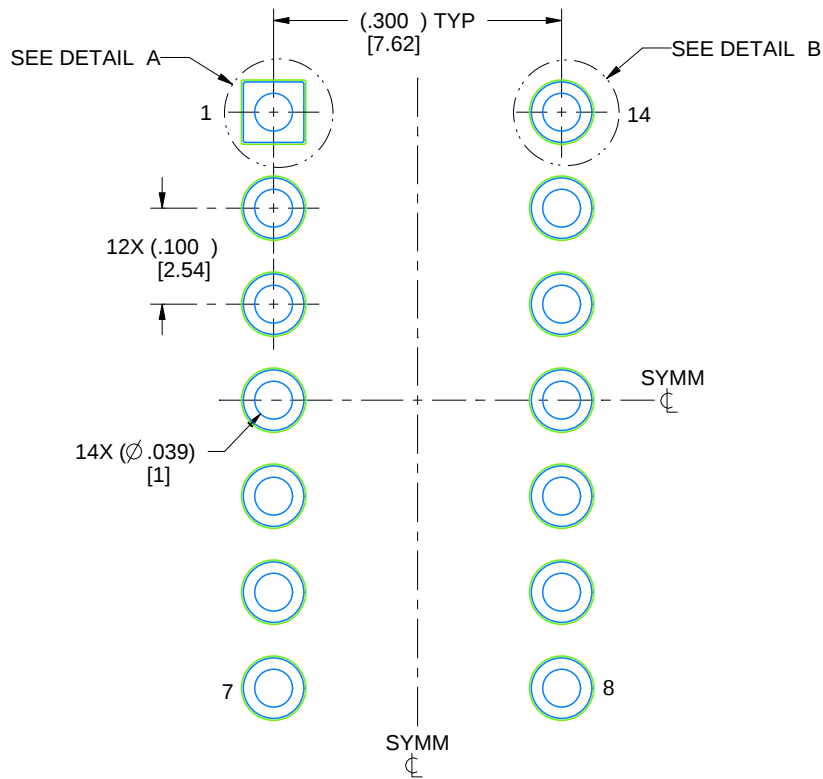
1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package is hermetically sealed with a ceramic lid using glass frit.
4. Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
5. Falls within MIL-STD-1835 and GDIP1-T14.

EXAMPLE BOARD LAYOUT

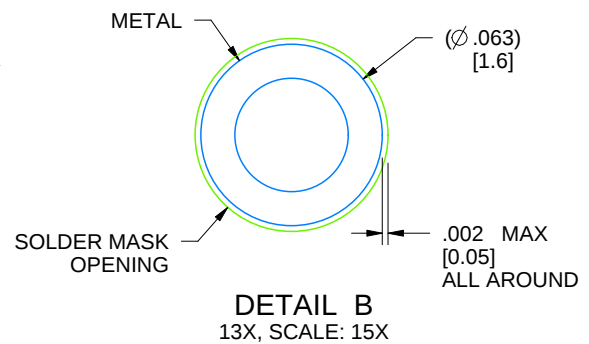
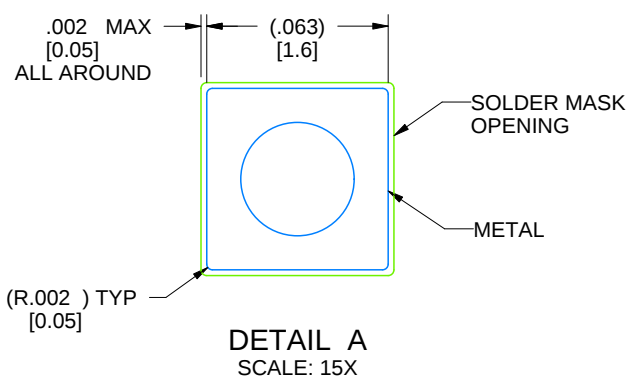
J0014A

CDIP - 5.08 mm max height

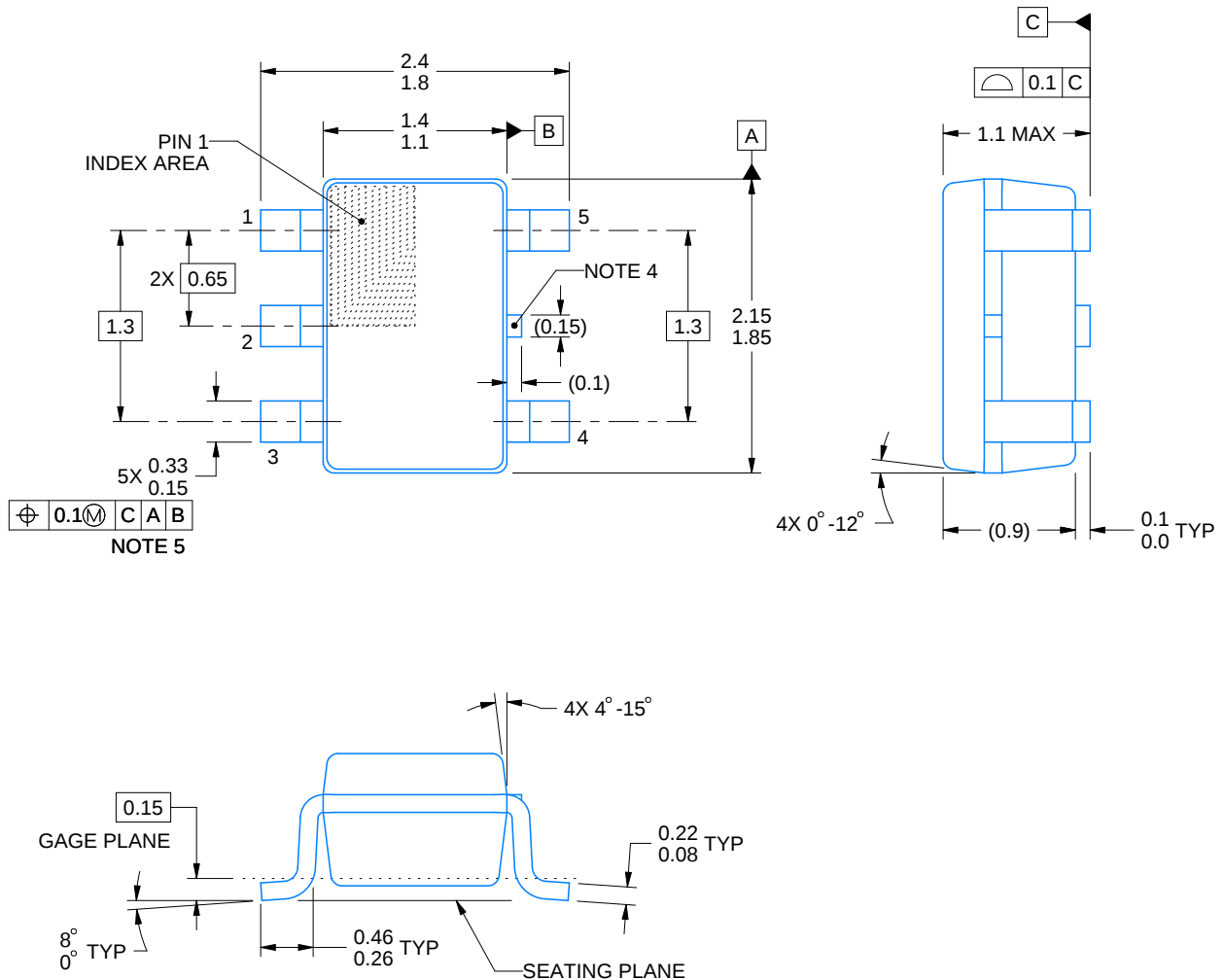
CERAMIC DUAL IN LINE PACKAGE



LAND PATTERN EXAMPLE
NON-SOLDER MASK DEFINED
SCALE: 5X



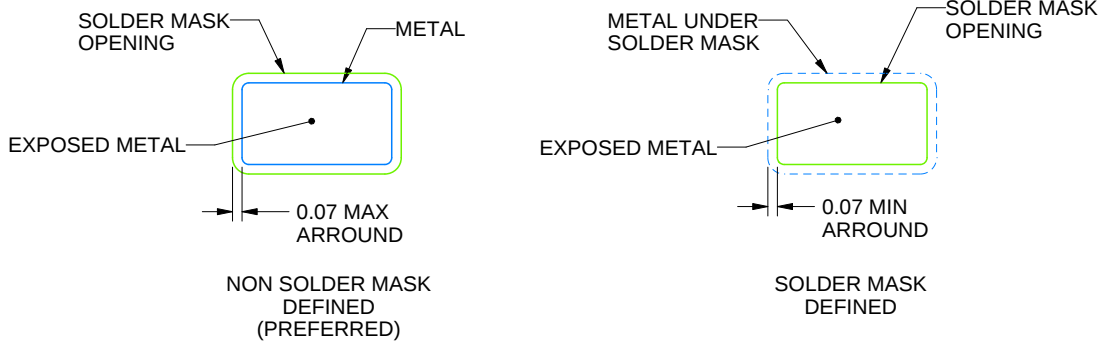
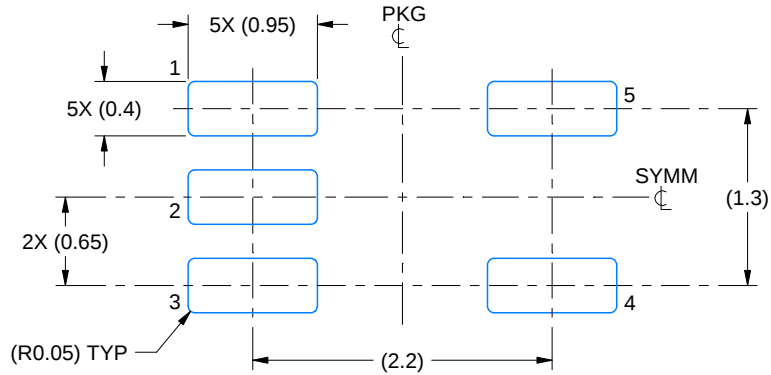
4214771/A 05/2017



4214834/G 11/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-203.
4. Support pin may differ or may not be present.
5. Lead width does not comply with JEDEC.
6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



4214834/G 11/2024

NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.
8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:18X

4214834/G 11/2024

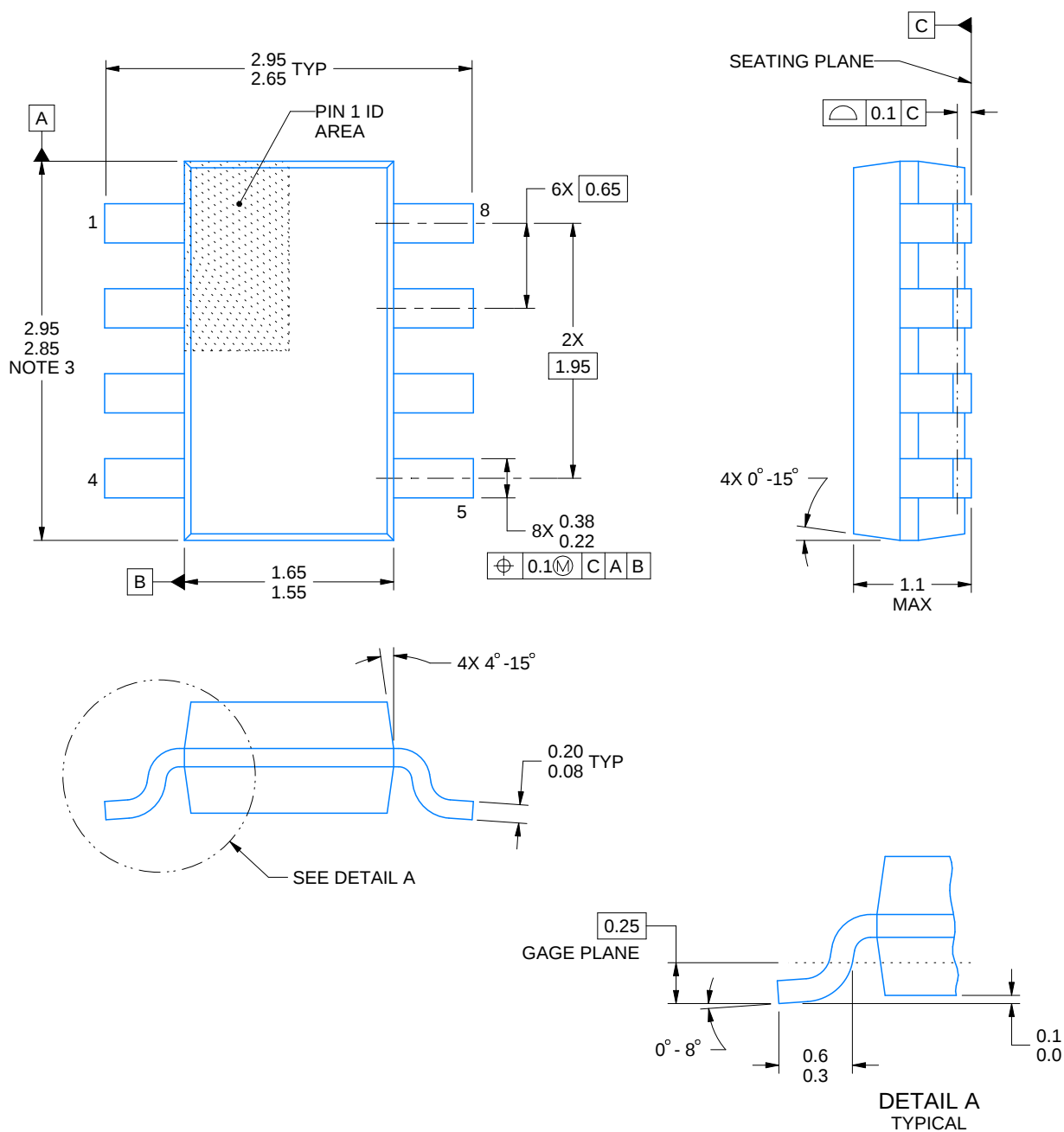
NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.



SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE



4222047/E 07/2024

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

2. This drawing is subject to change without notice.

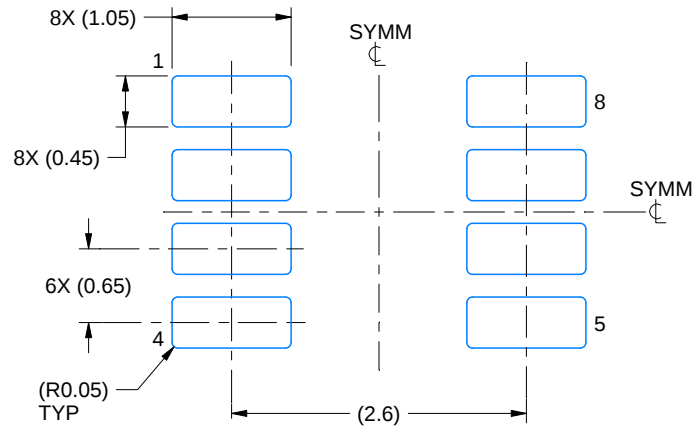
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.

EXAMPLE BOARD LAYOUT

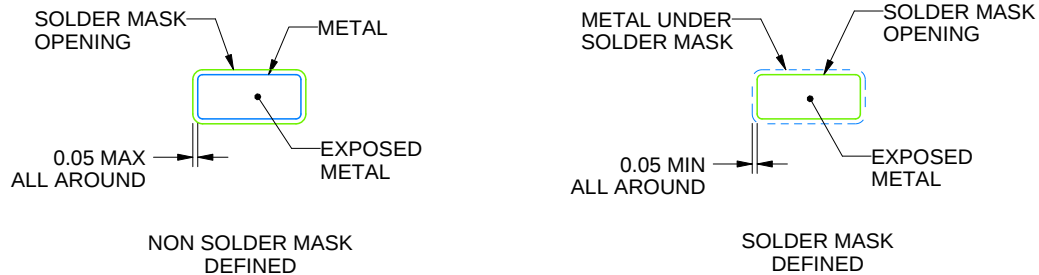
DDF0008A

SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4222047/E 07/2024

NOTES: (continued)

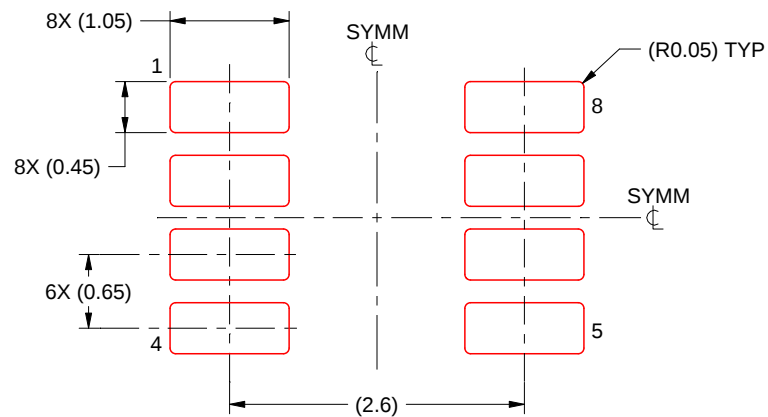
4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DDF0008A

SOT-23-THIN - 1.1 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4222047/E 07/2024

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



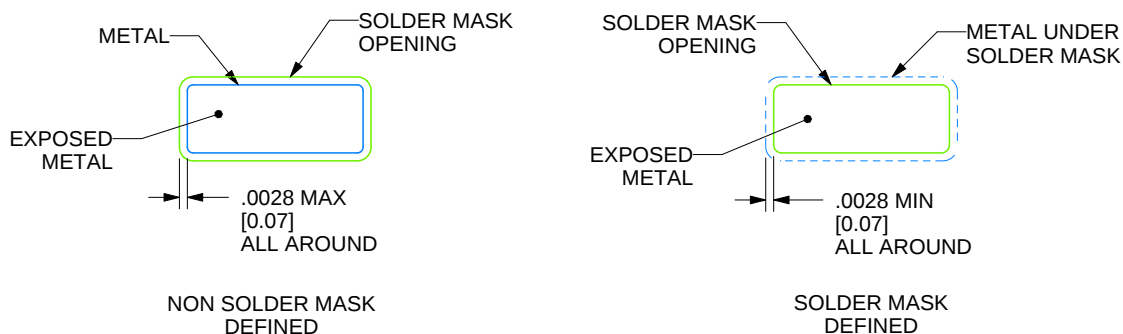
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

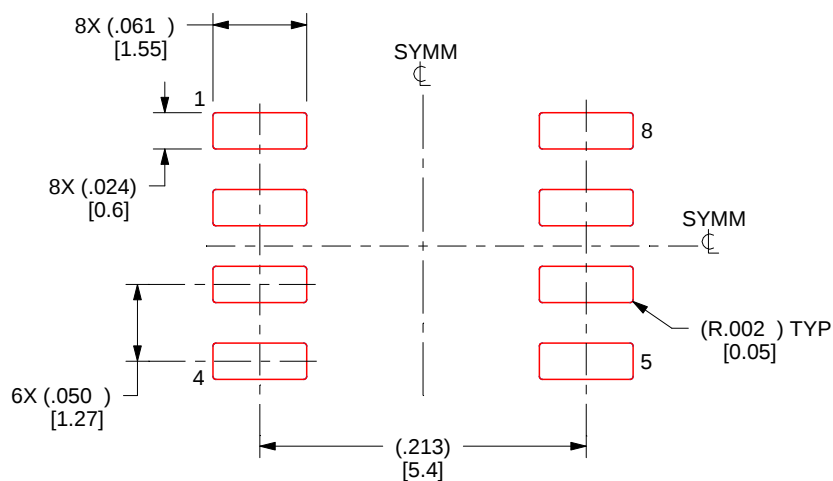
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

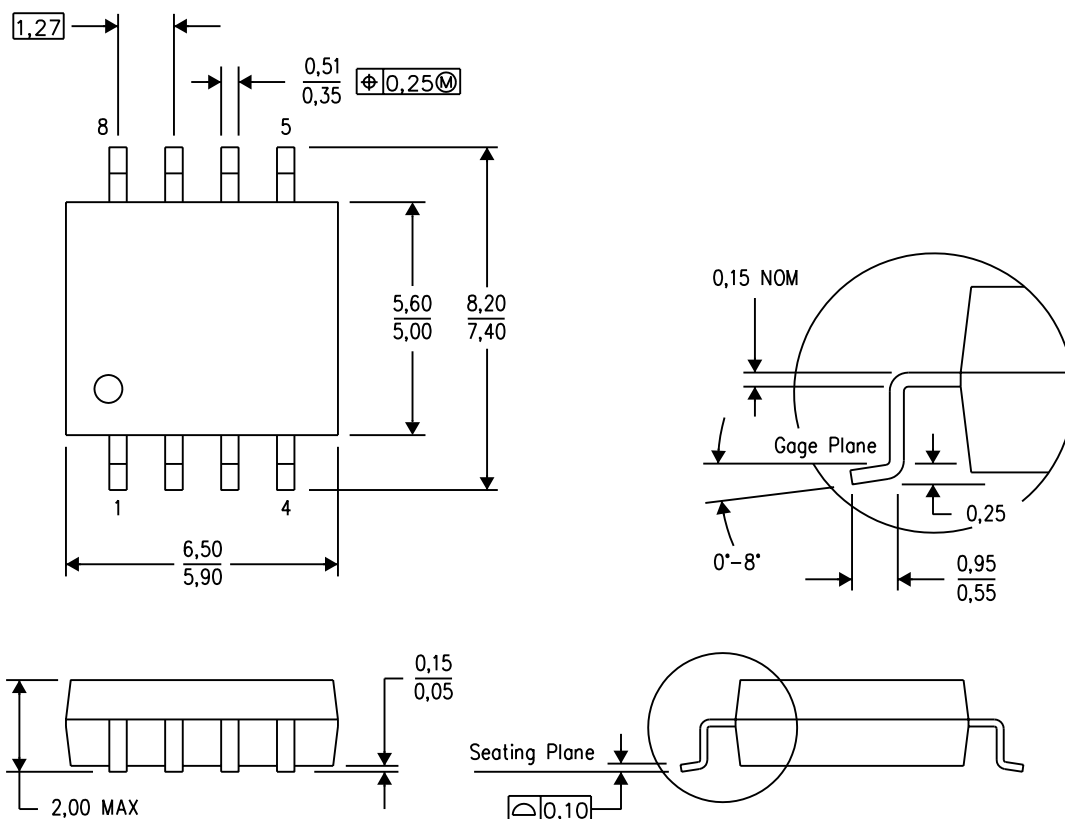
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

MECHANICAL DATA

PS (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE

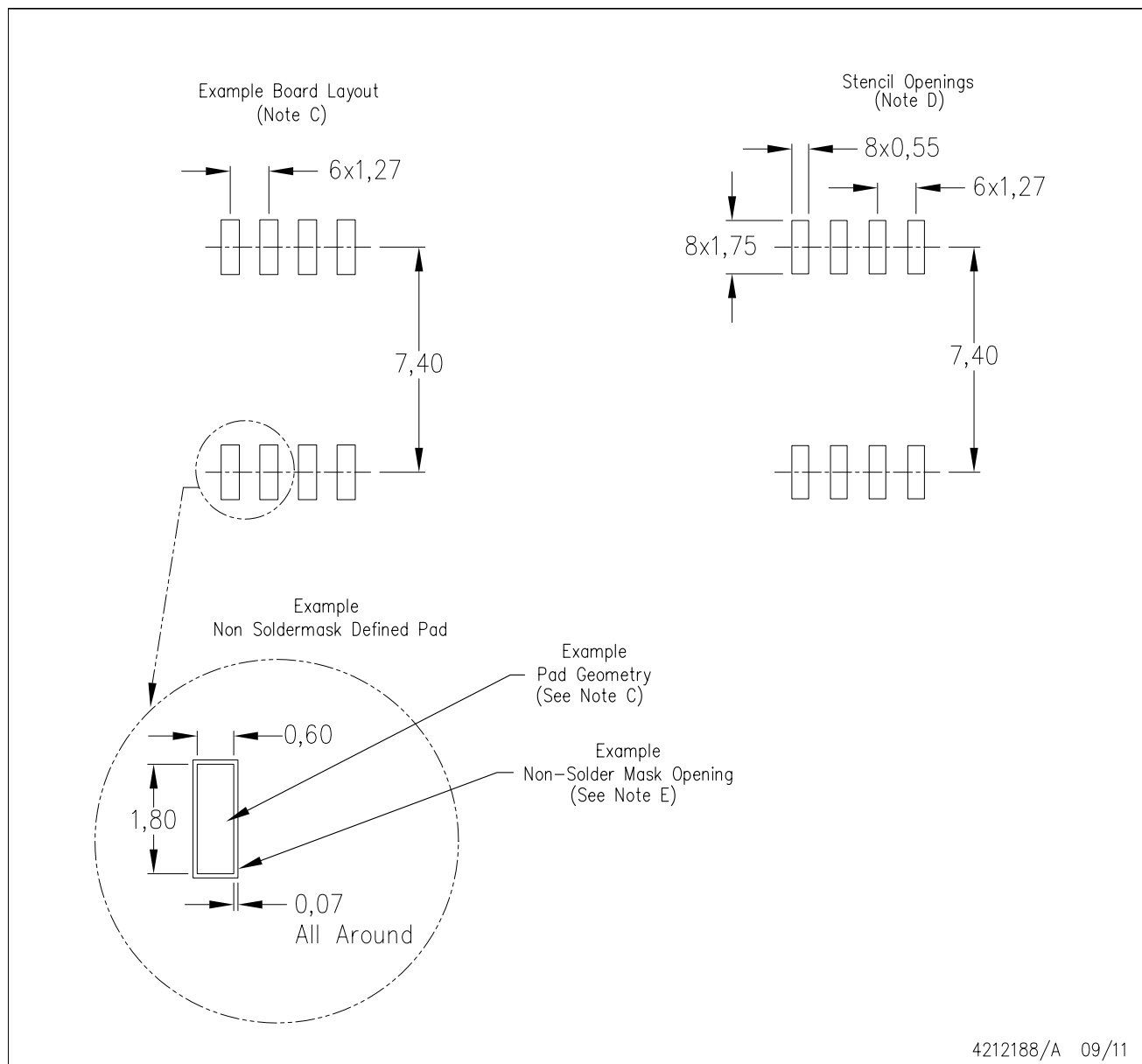


4040063/C 03/03

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

PS (R-PDSO-G8)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate designs.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.

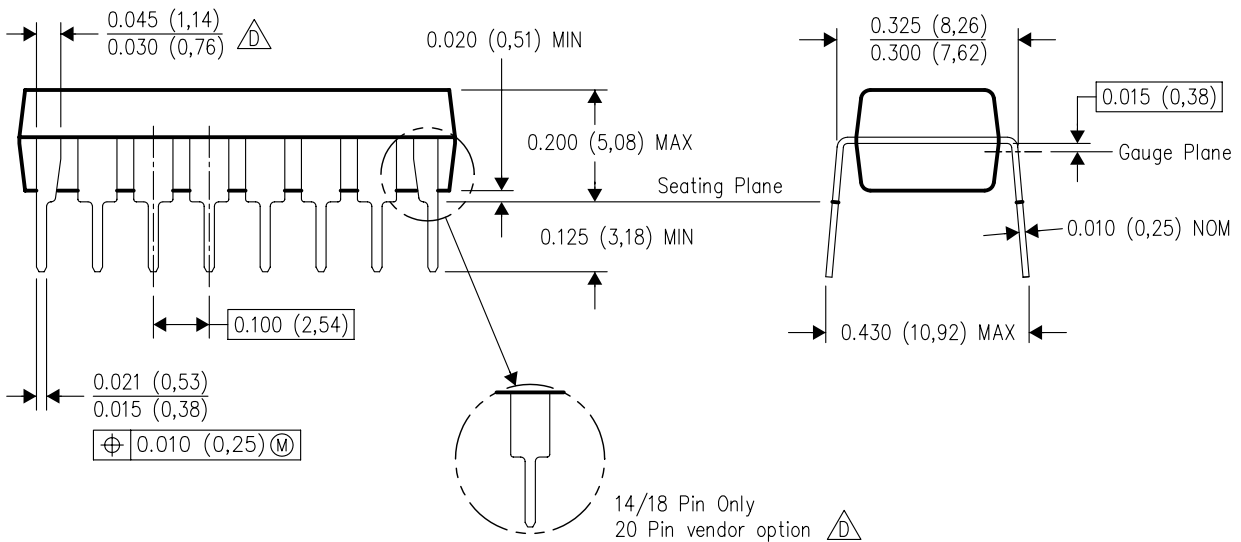
N (R-PDIP-T**)

16 PINS SHOWN

PLASTIC DUAL-IN-LINE PACKAGE



PINS **	14	16	18	20
DIM				
A MAX	0.775 (19,69)	0.775 (19,69)	0.920 (23,37)	1.060 (26,92)
A MIN	0.745 (18,92)	0.745 (18,92)	0.850 (21,59)	0.940 (23,88)
MS-001 VARIATION	AA	BB	AC	AD



14/18 Pin Only
20 Pin vendor option

4040049/E 12/2002

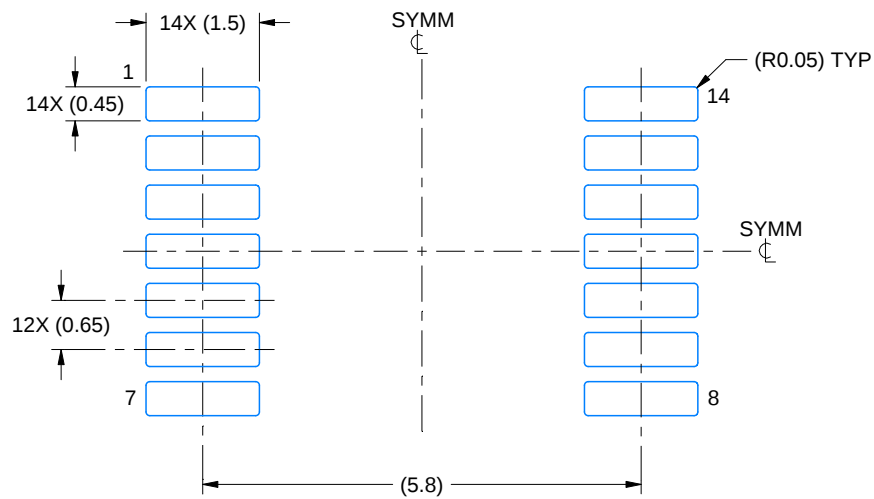
- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
 - The 20 pin end lead shoulder width is a vendor option, either half or full width.

EXAMPLE BOARD LAYOUT

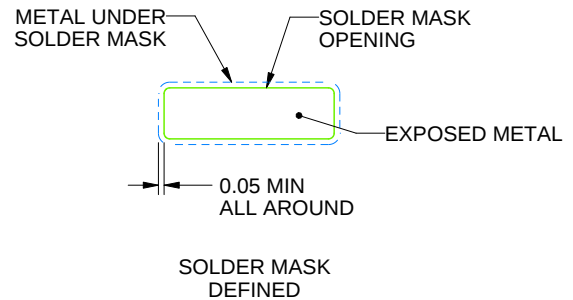
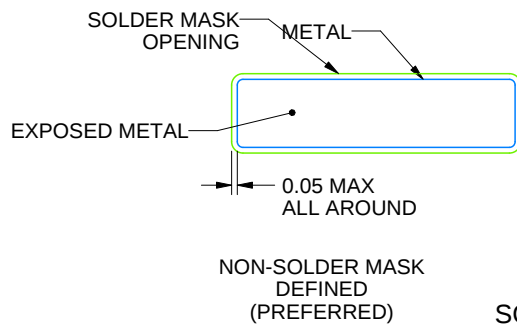
PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 10X



SOLDER MASK DETAILS

4220202/B 12/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

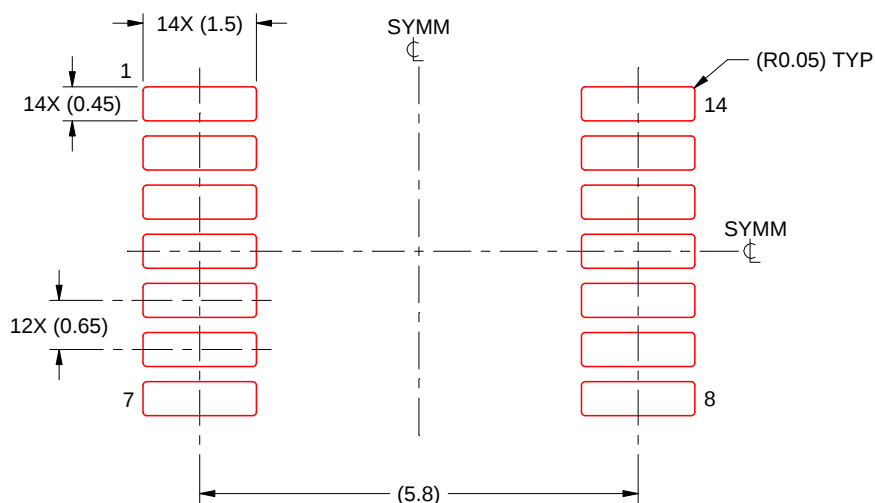
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0014A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4220202/B 12/2023

NOTES: (continued)

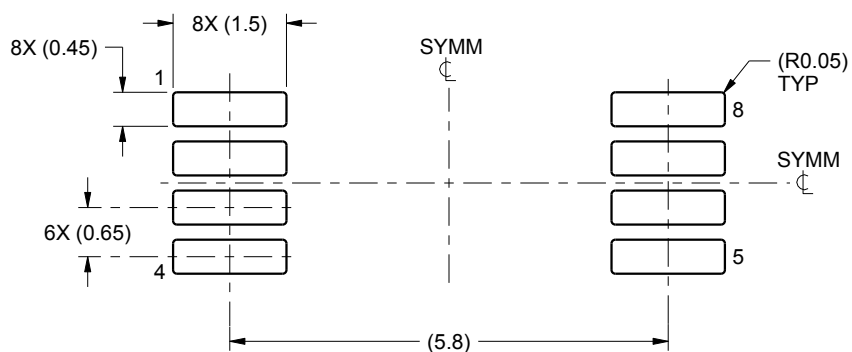
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

EXAMPLE BOARD LAYOUT

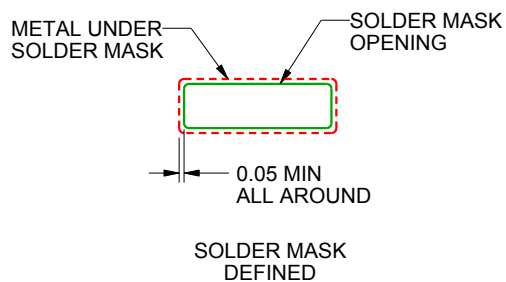
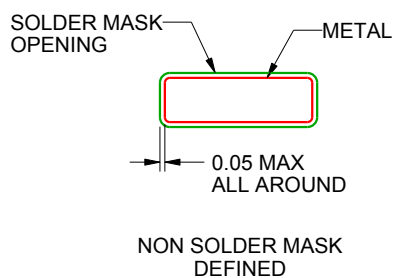
PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
SCALE:10X



SOLDER MASK DETAILS
NOT TO SCALE

4221848/A 02/2015

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

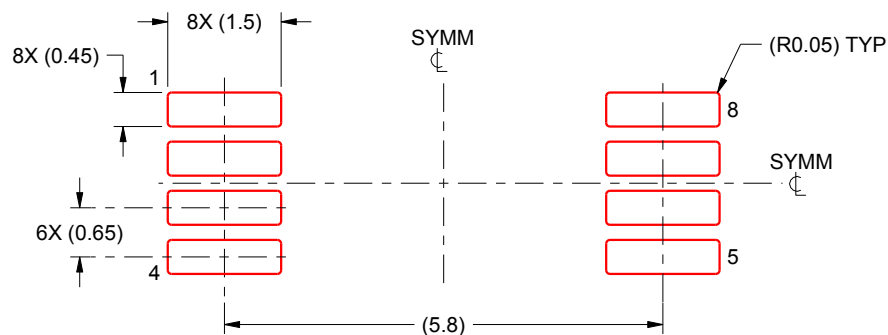
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

PW0008A

TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:10X

4221848/A 02/2015

NOTES: (continued)

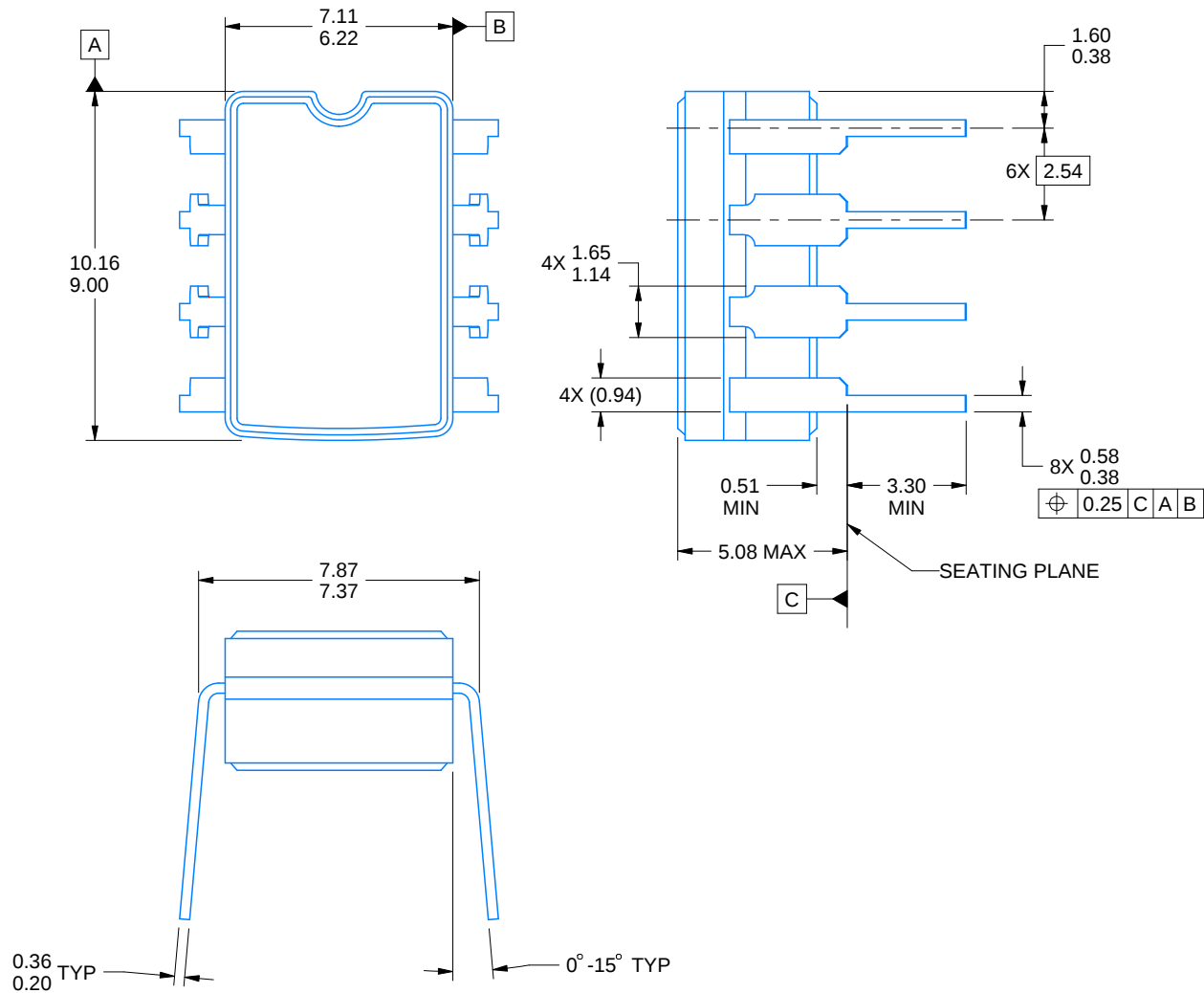
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

JG0008A

PACKAGE OUTLINE

CDIP - 5.08 mm max height

CERAMIC DUAL IN-LINE PACKAGE



4230036/A 09/2023

NOTES:

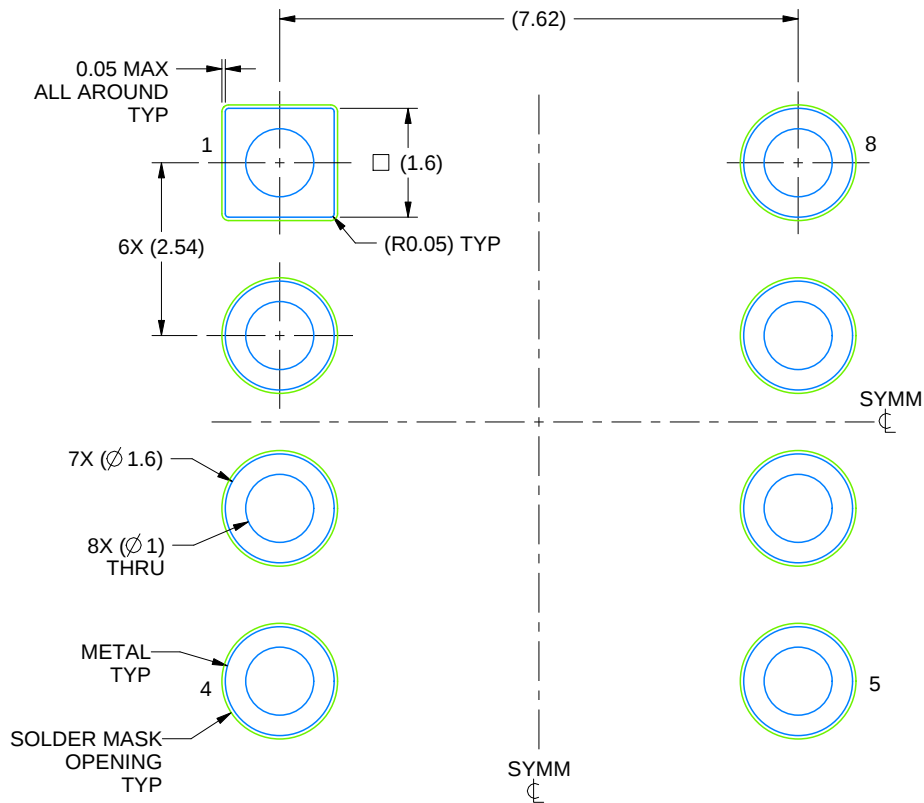
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This package can be hermetically sealed with a ceramic lid using glass frit.
4. Index point is provided on cap for terminal identification.
5. Falls within MIL STD 1835 GDIP1-T8

EXAMPLE BOARD LAYOUT

JG0008A

CDIP - 5.08 mm max height

CERAMIC DUAL IN-LINE PACKAGE

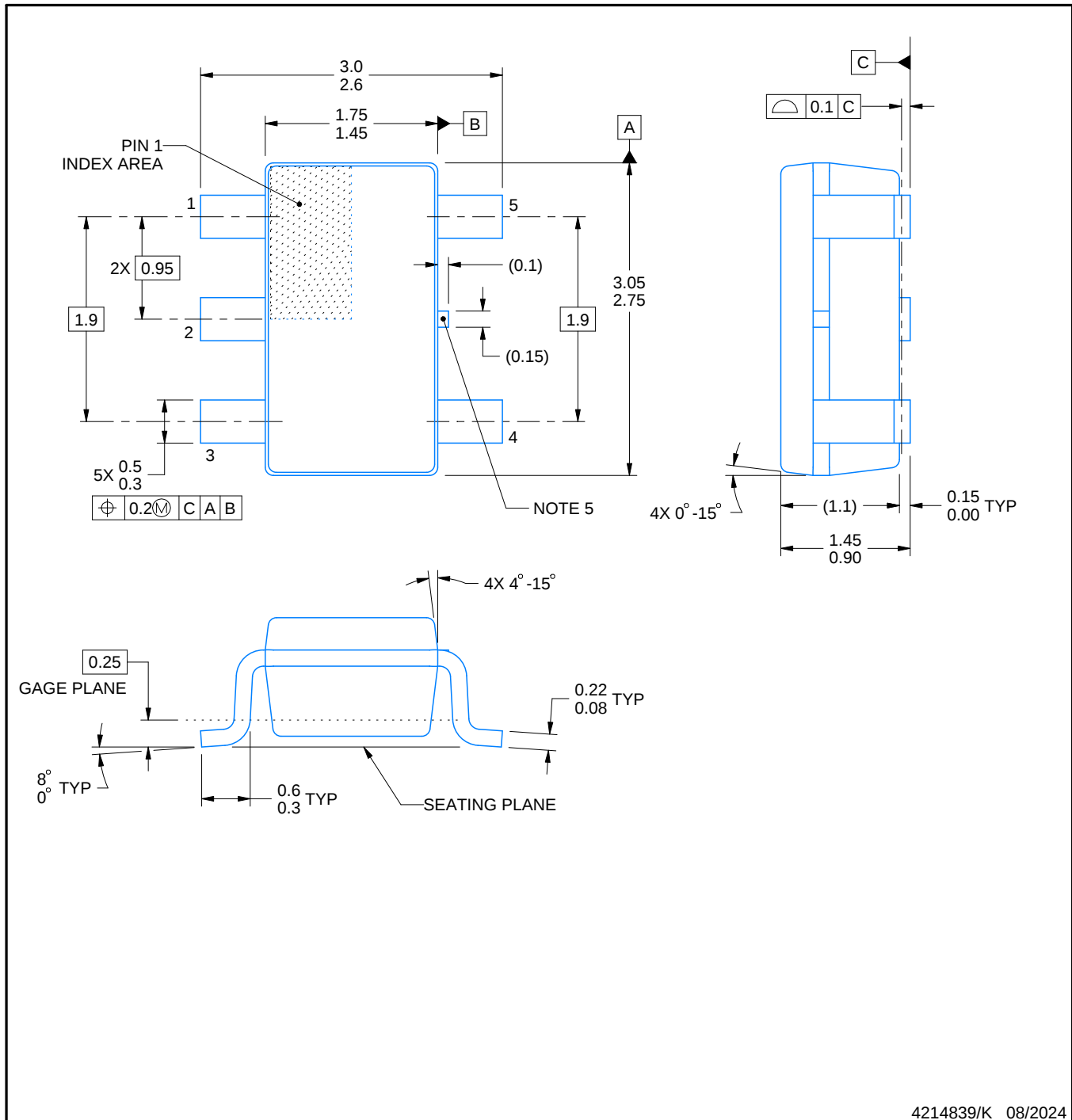


LAND PATTERN EXAMPLE
NON SOLDER MASK DEFINED
SCALE: 9X

4230036/A 09/2023

DBV0005A**PACKAGE OUTLINE****SOT-23 - 1.45 mm max height**

SMALL OUTLINE TRANSISTOR



4214839/K 08/2024

NOTES:

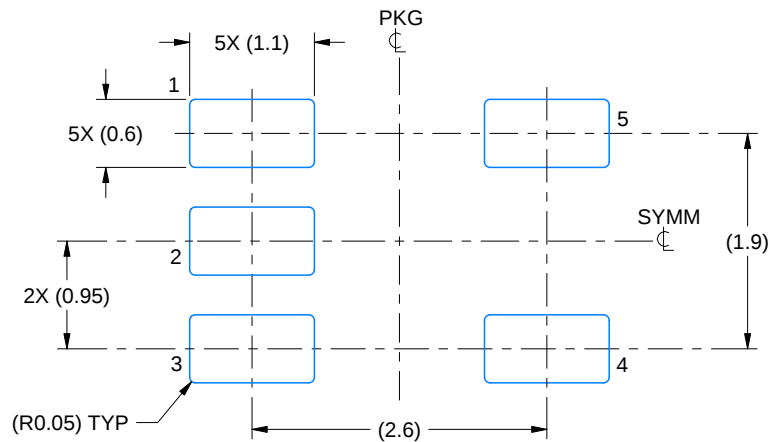
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

EXAMPLE BOARD LAYOUT

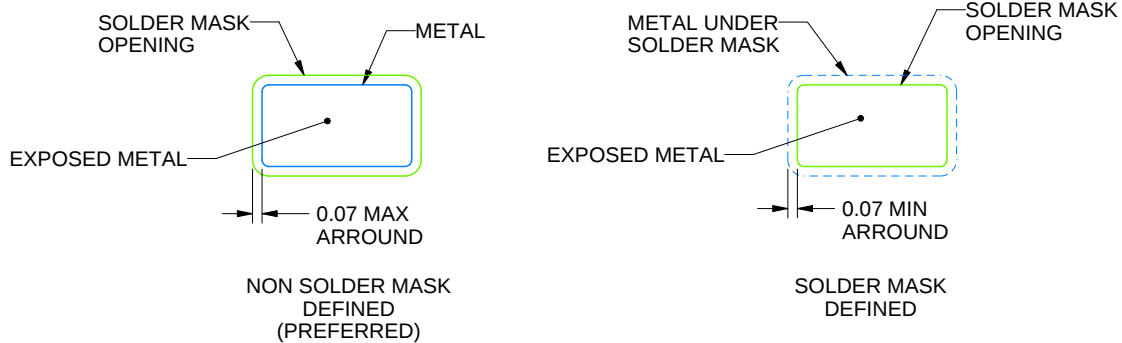
DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

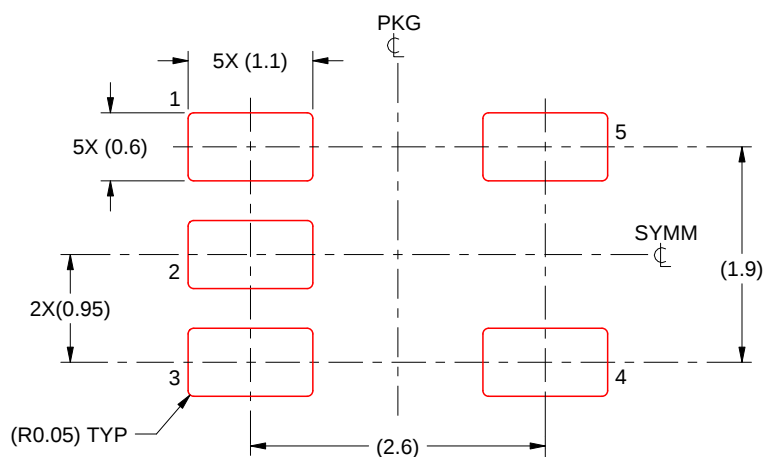
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR

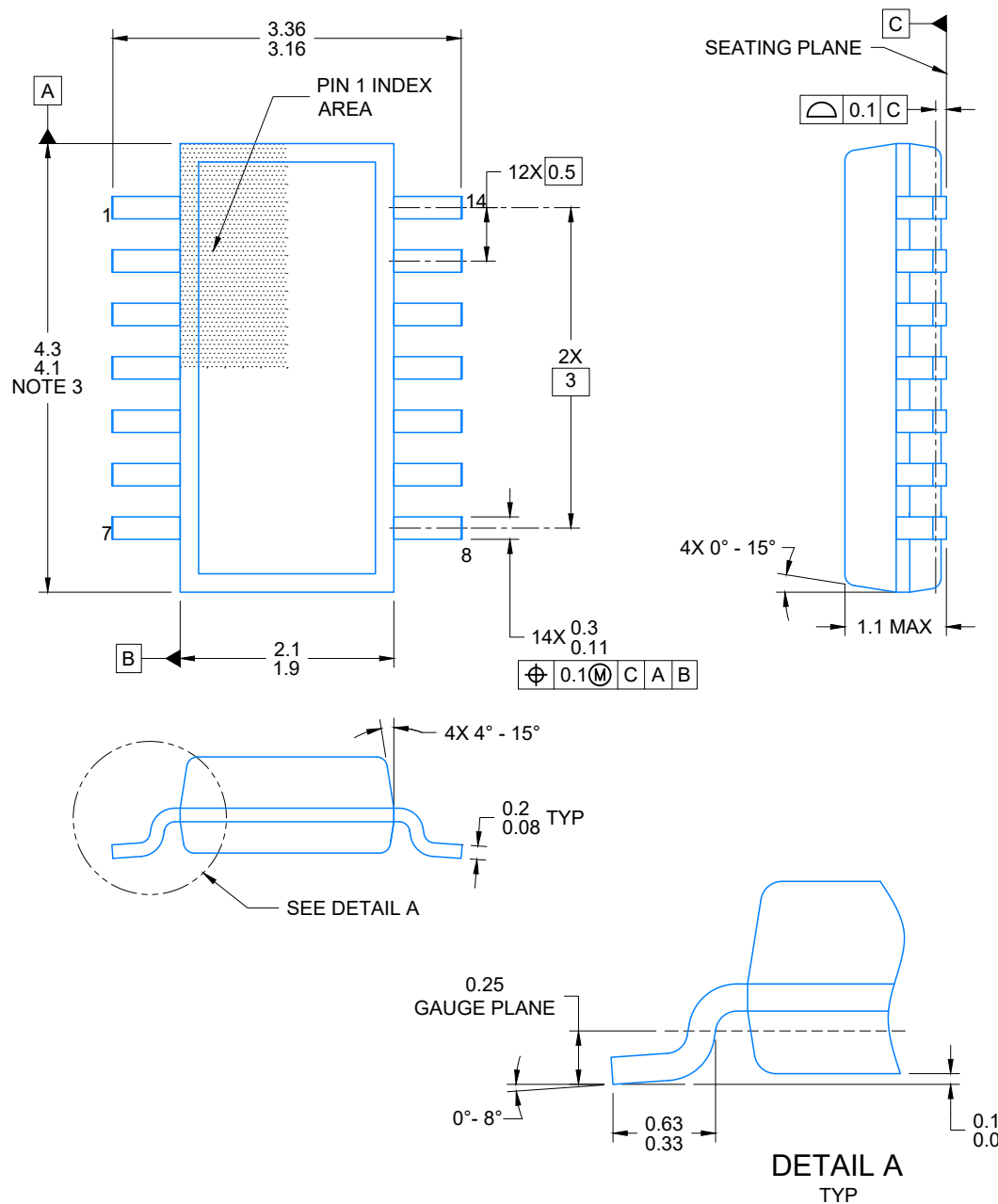


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

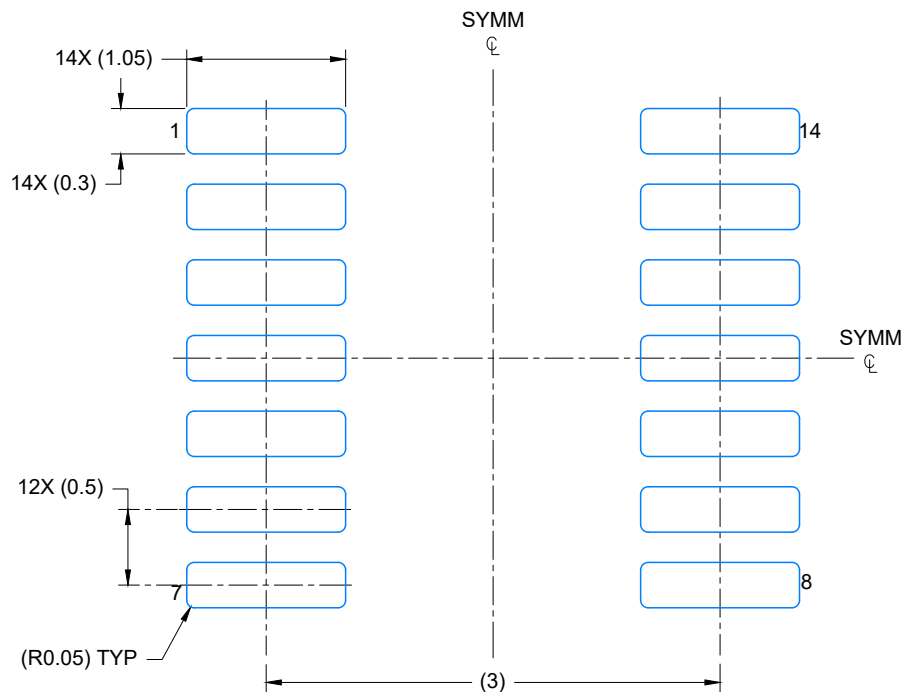
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



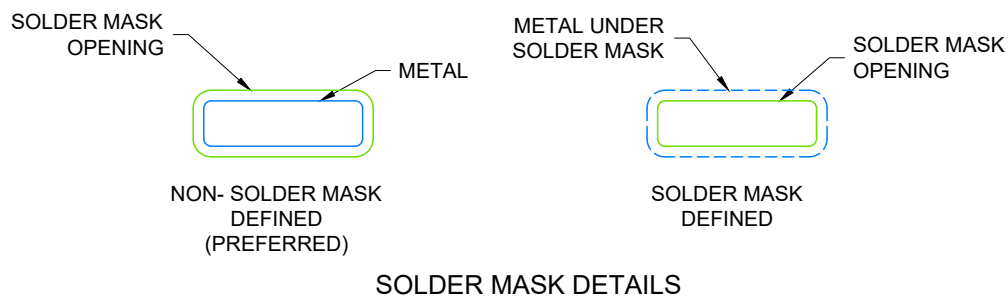
4224643/D 07/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
5. Reference JEDEC Registration MO-345, Variation AB



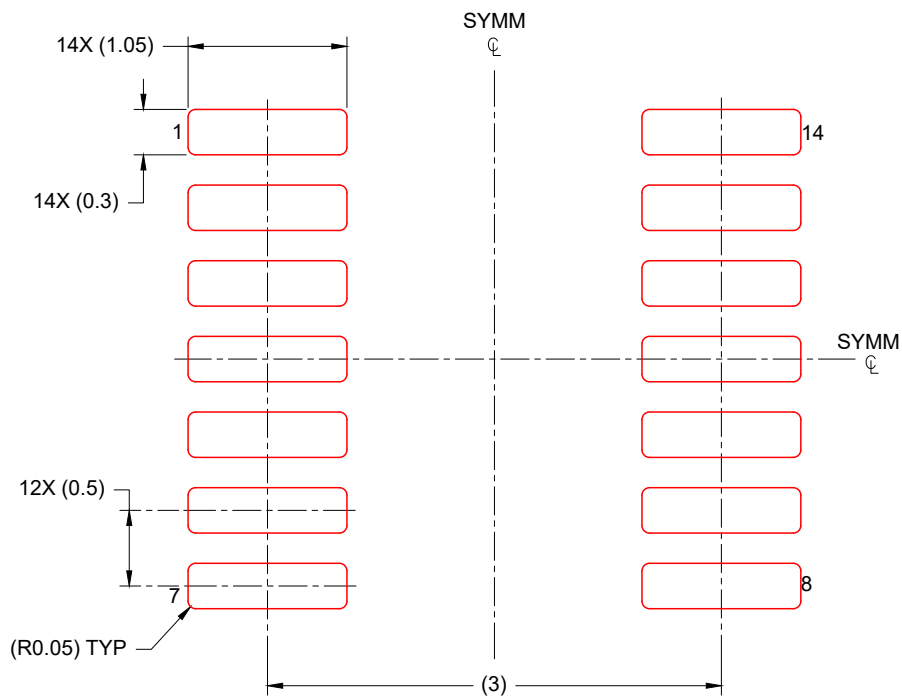
LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 20X



4224643/D 07/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

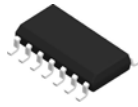


SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 20X

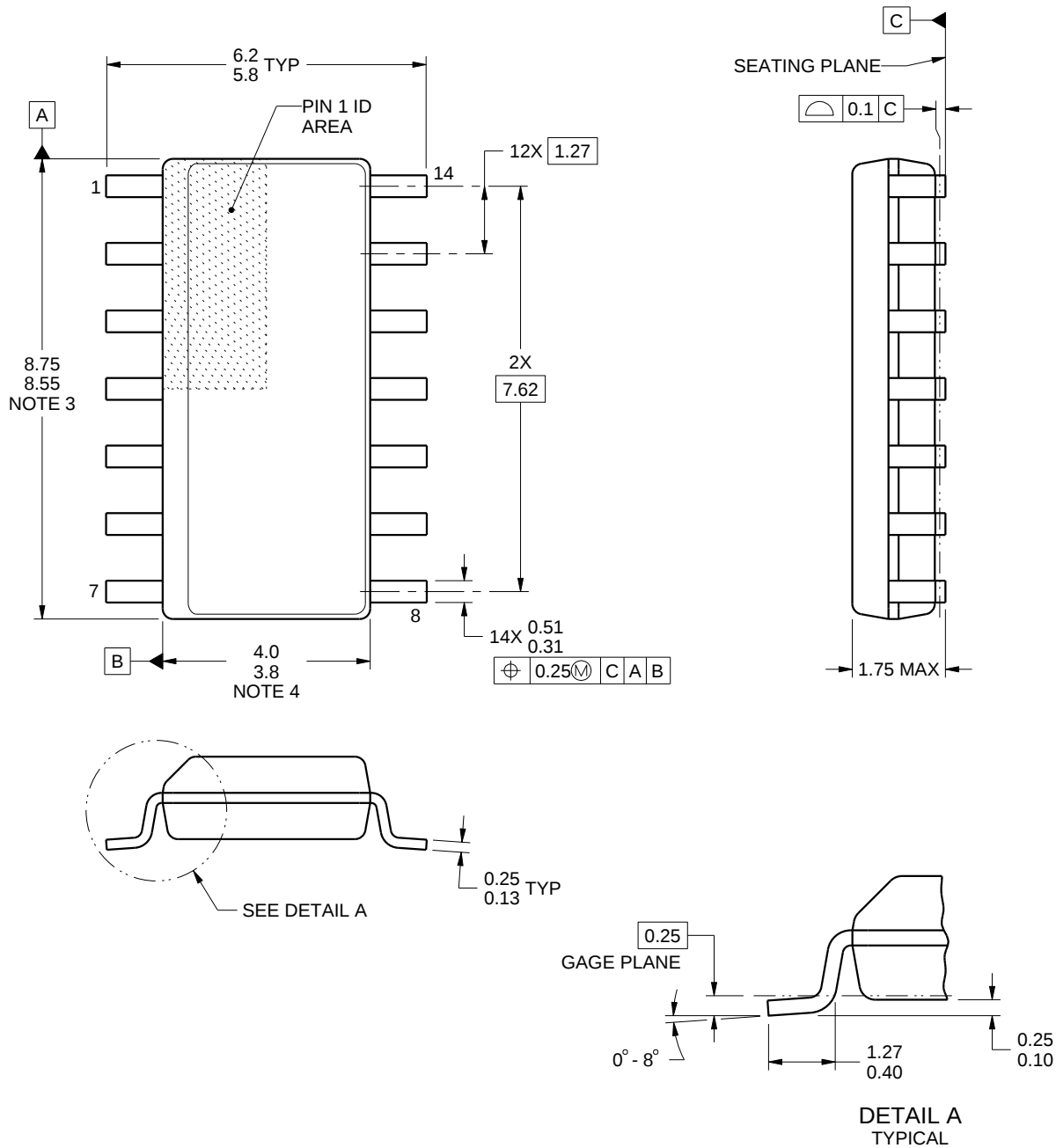
4224643/D 07/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

D0014A**PACKAGE OUTLINE****SOIC - 1.75 mm max height**

SMALL OUTLINE INTEGRATED CIRCUIT



4220718/A 09/2016

NOTES:

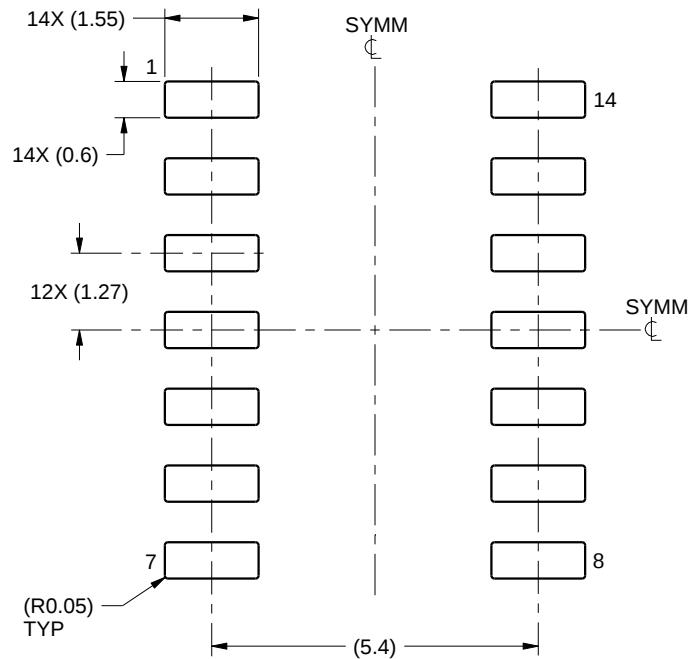
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
5. Reference JEDEC registration MS-012, variation AB.

EXAMPLE BOARD LAYOUT

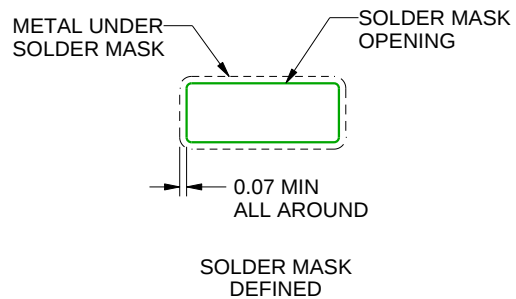
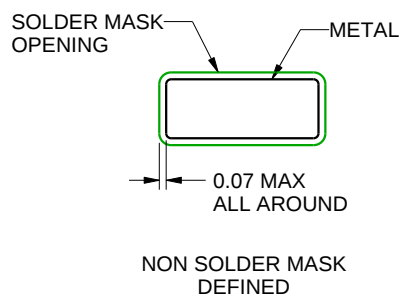
D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
SCALE:8X



SOLDER MASK DETAILS

4220718/A 09/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

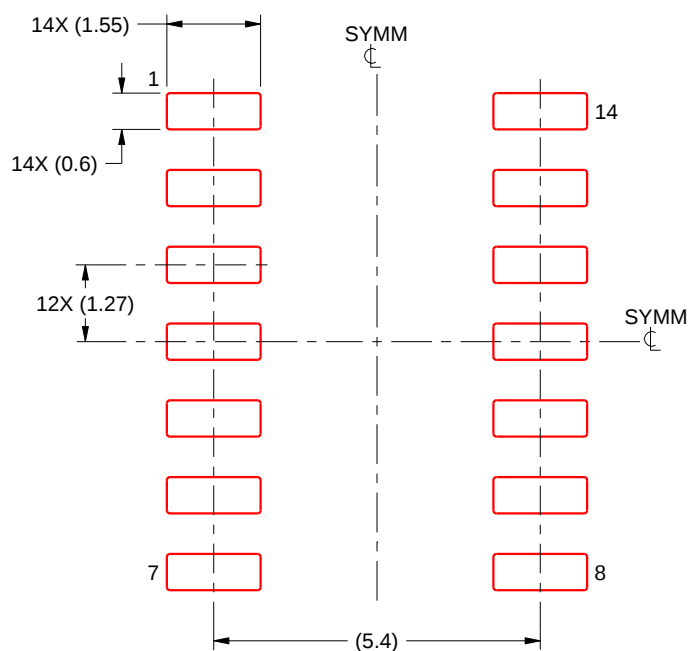
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0014A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:8X

4220718/A 09/2016

NOTES: (continued)

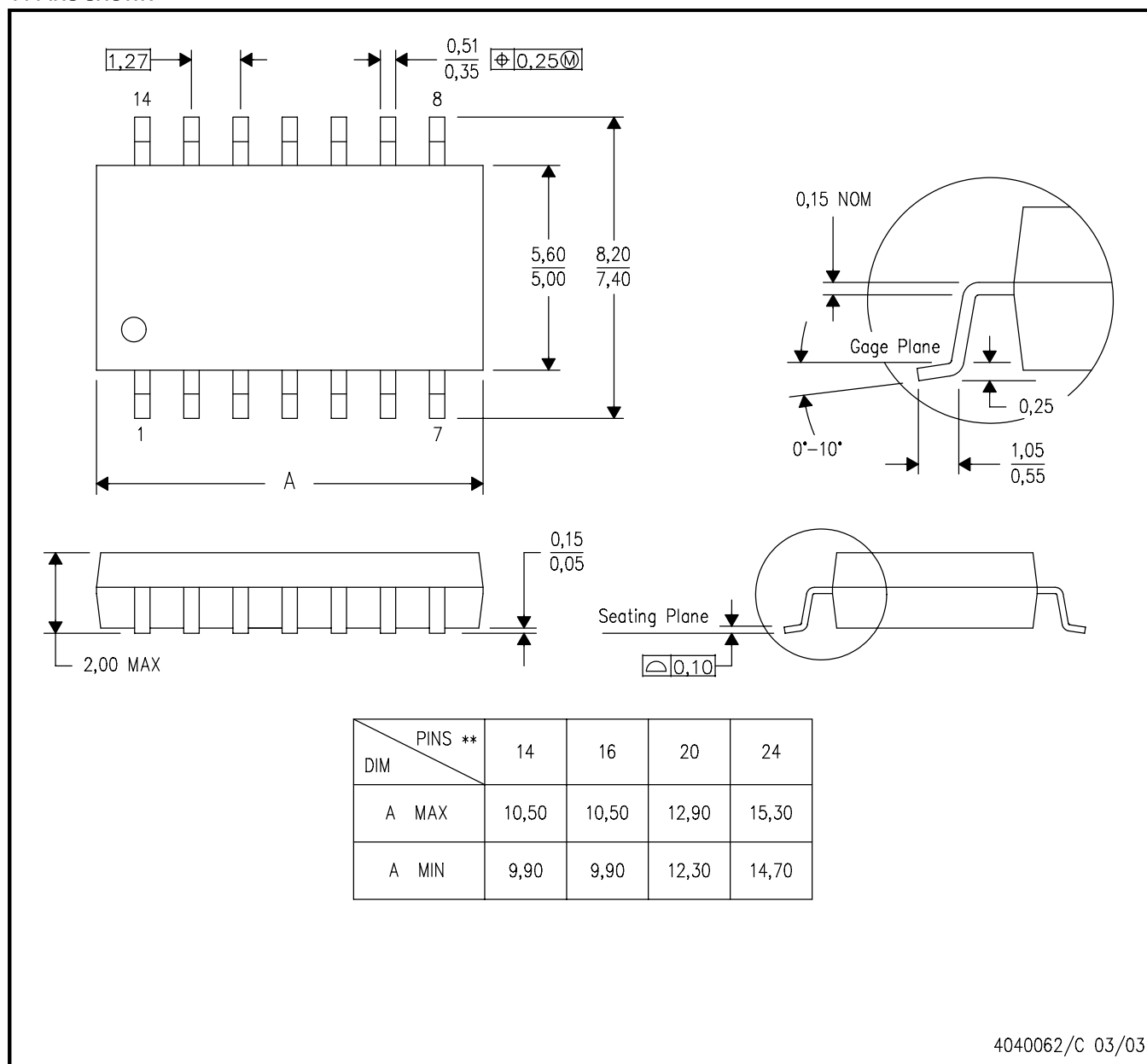
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

MECHANICAL DATA

NS (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14-PINS SHOWN



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

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